

## PCTEST

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## **HEARING AID COMPATIBILITY**

#### Applicant Name:

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Date of Testing: 10/26/2020 - 11/17/2020 **Test Site/Location:** PCTEST, Columbia, MD, USA **Test Report Serial No.:** 1M2009230152-20-R2.A3L Date of Issue: 12/9/2020

## FCC ID:

### A3LSMG998U

**APPLICANT:** 

### SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: Application Type: FCC Rule Part(s): HAC Standard:

DUT Type: Model: Additional Model(s): **Test Device Serial No.:**  **RF Emissions Testing** Certification CFR §20.19(b) ANSI C63.19-2011 CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017 285076 D01 HAC Guidance v05 285076 D02 T-Coil testing for CMRS IP v03 Portable Handset SM-G998U SM-G998U1 Pre-Production Sample [S/N: 0246M, 0766M, 3972S]

#### C63.19-2011 HAC Category:

## M3 (RF EMISSIONS CATEGORY)

Note: This revised Test Report (S/N: 1M2009230152-20-R1.A3L) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.









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## 1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658<sup>1</sup> to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

#### Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid *in-vitu* 

#### <sup>1</sup> FCC Rule & Order, WT Docket 01-309 RM-8658

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## 2. DUT DESCRIPTION



FCC ID: Manufacturer:

Additional Model(s):

Antenna Configurations:

Serial Number:

DUT Type:

Model:

A3LSMG998U Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea SM-G998U SM-G998U1 0246M, 0766M, 3972S Internal Antenna Portable Handset

#### I. Power Reduction for WIFI

This device uses an independent fixed level power reduction mechanism for all WIFI operations during voice or VoIP held to ear scenarios. Reduced powers were used to evaluate for low-power exemption in Section 9.II for WIFI. Detailed descriptions of the power reduction mechanism are included in the operational description.s

#### II. LTE Band Selection

This device supports the following pairs of LTE bands with similar frequencies: LTE B4 & B66 and B38 & B41. Each pair of LTE bands has the same target power and shares the same transmission path. Since the supported frequency spans for the smaller LTE bands are completely covered by the larger LTE bands, only the larger LTE bands (LTE B66 and B41) were evaluated for hearing-aid compliance. LTE B5 and B2 are LTE anchor bands for dual connectivity (EN-DC) scenarios between LTE and NR so they were additionally evaluated as independent LTE bands.

#### III. NR Band Selection

This device supports the following pair of NR bands with similar frequencies: NR n2 & n25. This pair of NR bands has the same target power and shares the same transmission path. Since the supported frequency span for the smaller NR band is completely covered by the larger NR band, only the larger NR band (NR n25) was evaluated for hearing-aid compliance.

#### IV. Device Serial Numbers

Several samples with identical hardware were used to support HAC testing. The manufacturer has confirmed that the device(s) tested have the same physical, mechanical, and thermal characteristics are within operational tolerances expected for production units. The serial numbers used for each test are indicated alongside the results in Section 11.

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		AJL		U HAC Air Interfaces		
Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service	
CDMA	835 1900	VO	Yes	Yes: WIFI or BT	CMRS Voice	
	EvDO	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo	
GSM	850 1900	VO	Yes	Yes: WIFI or BT	CMRS Voice	
	GPRS/EDGE	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo	
	850					
	1700	VD	No <sup>1</sup>	Yes: WIFI or BT	CMRS Voice	
UMTS	1900					
	HSPA	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo	
	680 (B71)		No <sup>1 2</sup>			
	700 (B12)					
	780 (B13)					
	790 (B14)					
	850 (B5)					
LTE (FDD)	850 (B26)	VD		Yes: WIFI or BT	VoLTE, Google Duo	
	1700 (B4)		No <sup>1</sup>			
	1700 (B66)					
	1900 (B2)					
	1900 (B25)					
	2300 (B30)					
	2500 (B7)					
	2600 (B38)					
LTE (TDD)	2600 (B41)	VD	Yes	Yes: WIFI or BT	VoLTE, Google Duo	
	3600 (B48)		NI-12			
	680 (n71)		No <sup>12</sup>			
	700 (n12)					
	850 (n5)	VD		Yes: WIFI or BT	Caasla Dua	
NR (FDD)	1700 (n66) 1900 (n2)	VD	No <sup>1</sup>	Tes. WIFI OF BI	Google Duo	
	1900 (n25)					
	2300 (n30)					
	2600 (n41)					
	3750 (n77)		Yes			
NR (TDD)	28000 (n261)	VD		Yes: WIFI or BT	Google Duo	
	39000 (n260)		No <sup>3</sup>			
	2450					
	5200 (U-NII 1)					
	5300 (U-NII 2A)		No <sup>1</sup>			
	5500 (U-NII 2C)					
WIFI	5800 (U-NII 3)	VD		Yes: CDMA, GSM, UMTS, LTE, or NR	VoWIFI, Google Duo	
	6175 (U-NII 5)					
	6475 (U-NII 6)		No <sup>4</sup>			
	6700 (U-NII 7)		INO			
	7000 (U-NII 8)					
BT	2450	DT	No	Yes: CDMA, GSM, UMTS, LTE, or NR	N/A	
Type Transport VO = Voice Onl			Notes:	or MIE and low power examption		
				or MIF and low-power exemption. d NR n71, while outside the scope of ANSI C63.19	and FCC HAC regulations, were	
	I/or IP Voice over Dat		additionally ev equipment.	valuated according to the existing HAC procedure 261 were not evaluated due to equipment limitat	s with currently available test	
			ANSI C63.19 a 4. WIFI U-NII k	nd FCC HAC regulations. ands 5 through 8 were not evaluated due to equ INSI C63.19 and FCC HAC regulations.		
			the scope of A	and costs and fee the regulations.		

## Table 2-1 A3LSMG998U HAC Air Interfaces

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#### ANSI/IEEE C63.19 PERFORMANCE CATEGORIES 3.

## I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters			
Near field Category	E-field emissions CW dB(V/m)			
	f < 960 MHz			
M1	50 to 55			
M2	45 to 50			
M3	40 to 45			
M4	< 40			
f > 960 MHz				
M1	40 to 45			
M2	35 to 40			
M3	30 to 35			
M4	< 30			
Table 3-1WD near-field categories as defined in ANSI C63.19-2011				

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## 4. SYSTEM SPECIFICATIONS

#### EF3DV3 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis
Calibration:	Built-in shielding against static charges In air from 30 MHz to 6.0 GHz (absolute accuracy ±5.1%, k=2)
Frequency:	30 MHz to > 6 GHz;
	Linearity: ± 0.2 dB (30 MHz to 6 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis)
	± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m
	(M3 or better device readings fall well below diode
	compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 337 mm (Tip: 20 mm)
	Tip diameter: 4.0 mm (Body: 12 mm)
	Distance from probe tip to dipole centers: 1.5 mm

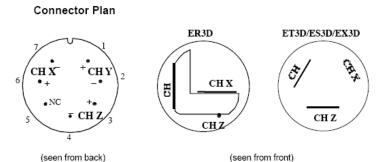


**Figure 4-1** E-field Free-space Probe

#### **Probe Tip Description**

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement").



The antistatic shielding inside the probe is connected to the probe connector case.

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#### Instrumentation Chain

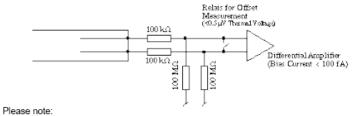
#### Equation 1 Conversion of Connector Voltage *u<sub>i</sub>* to E-Field *E<sub>i</sub>*

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

Ei:	electric field in V/m
Uj.	voltage of channel i at the connector in μV
Norm	sensitivity of channel i in µV/(V/m) <sup>2</sup>
ConvF:	enhancement factor in liquid (ConvF=1 for Air)
DCP:	diode compression point in µV
CF:	signal crest factor (peak power/average power)

#### **Conditions of Calibration**



a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP

larger bias currents will cause higher offset

#### **Probe Response to Frequency**

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

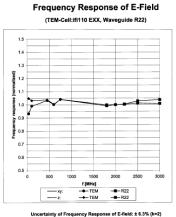


Figure 4-2 E-Field Probe Frequency Response

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#### **SPEAG Robotic System**

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich. Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 4-3 SPEAG Robotic System

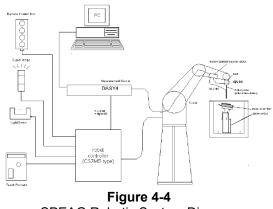
#### System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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#### System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



SPEAG Robotic System Diagram

#### **DASY5** Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with	$V_i$	= compensated signal of channel i	(i = x, y, z)
	$U_i$	= input signal of channel i	(i = x, y, z)
	cf	= crest factor of exciting field	(DASY parameter)
	$dcp_i$	= diode compression point	(DASY parameter)

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From the compensated input signals the primary field data for each channel can be evaluated:

E – fieldprobes : 
$$E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with 
$$V_i$$
 = compensated signal of channel i (i = x, y, z)  
 $Norm_i$  = sensor sensitivity of channel i (i = x, y, z)  
 $\mu V/(V/m)^2$  for E-field Probes  
 $ConvF$  = sensitivity enhancement in solution  
 $E_i$  = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

#### **Environmental Conditions**

Environmental conditions such as temperature and relative humidity are monitored to ensure there are no impacts on system specifications. Proper voltage and power line frequency conditions are maintained with three phase power sources. Environmental noise and reflections are monitored through system checks.

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## 5. TEST PROCEDURE

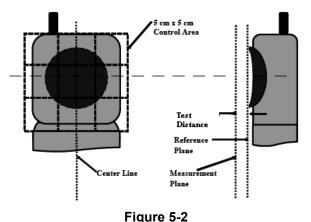
#### I. RF EMISSIONS

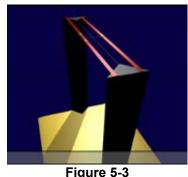
**Test Instructions Confirm proper operation of**  $\geq$ probes and instrumentation Position WD  $\succ$ **Configure WD TX operation** ≻ Per 5.5.1.2 (a-c) Initialize field probe  $\triangleright$ Scan Area ≻ Per 5.5.1.2 (d-f) Identify exclusion area.  $\geq$  $\geq$ Rescan or reanalyze open area to determine maximum Indirect method: Add the MIF  $\geq$ to the maximum steady state rms field strength and record **RF** Audio Interference Level, in dB(V/m) Per 5.5.1.2 (g-h) & 5.5.1.3 Identify and record the ≻ category Per 5.5.1.2 (i-j)

Figure 5-1 RF Emissions Flow Chart

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#### **Test Setup**





HAC Phantom

### E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

#### **RF Emissions Test Procedure:**

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. Of the 9 subgrids (see Figure 5-2), 3 contiguous subgrids may be excluded from the measurement in order to account for localized areas of higher field intensities. The center subgrid containing the acoustic output or audio band magnetic output may not excluded. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

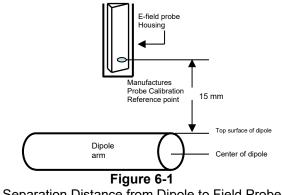
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## 6. SYSTEM CHECK

#### I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

#### **II. Validation Procedure**

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

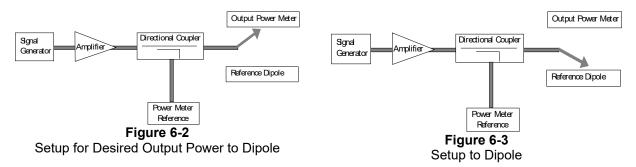
The length of the dipole was scanned, and the average peak value was recorded.

#### Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

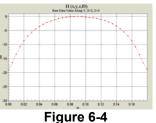
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RF power was recorded using both an average and a peak power reading meter.

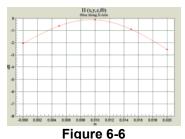


Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



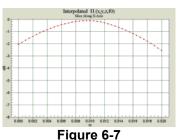
2-D Raw Data from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along dipole axis



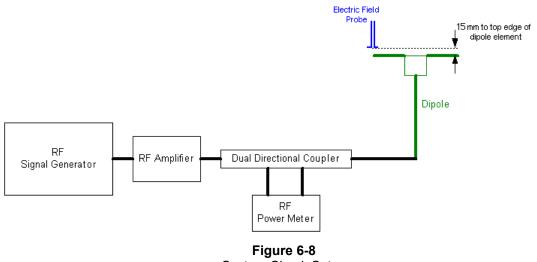
2-D Interpolated points from scan along transverse axis

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## **III. System Check Results**

### Validation Results

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation			
11/2/2020	835			1003	20.0	110.9	105.2	5.4%			
11/2/2020	1880			1137	20.0	89.0	87.8	1.4%			
10/26/2020	2600	4025	4035	4035	4025	665	1012	20.0	87.6	85.2	2.8%
11/16/2020	2600	4035	005	1012	20.0	88.5	85.2	3.9%			
10/28/2020	3500			1005	20.0	85.7	84.1	1.9%			
11/16/2020	3500			1005	20.0	87.9	84.1	4.5%			



System	Check Setup

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## 7. MODULATION INTERFERENCE FACTOR

## I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- 5. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

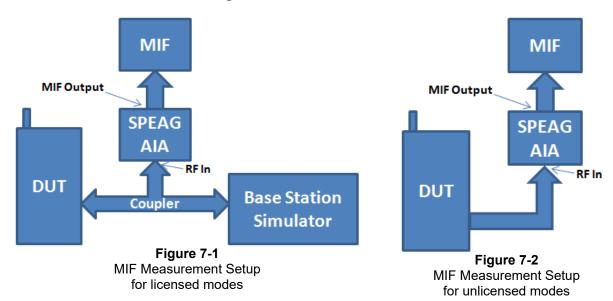
The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

#### Audio Interference Level [dB(V/m)] = 20 \* log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

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## **II. MIF Measurement Block Diagrams**



#### III. Measured Modulation Interference Factors:

	Table 7-1										
	CDMA Modulation Interference Factors <sup>1</sup>										
			С	ell			PCS				
Mc	ode	90S	22H	22H	22H	24E	24E	24E			
564 1013 384 777						25	600	1175			
	RC1/SO3	3.08	3.11	3.05	3.07	3.07	3.07	3.04			
CDMA	RC1/SO55	-19.79	-19.68	-19.64	-19.78	-19.58	-19.61	-19.62			
	EvDO	-18.84	-19.17	-19.09	-19.22	-19.15	-18.98	-19.11			

 Table 7-2

 GSM Modulation Interference Factors1

 GSM850

Mode			GSM850		GSM1900			
		128	190	251	512	661	810	
GSM	Voice	3.56	3.56	3.55	3.53	3.54	3.55	
	EDGE	3.72	3.73	3.72	3.74	3.76	3.76	

 Table 7-3

 UMTS Modulation Interference Factors<sup>1</sup>

Mode			UMTS V			UMTS IV		UMTS II			
		4132	4183	4233	1312	1412	1513	9262	9400	9538	
	12.2 kbps RMC	-13.22	-14.15	-12.80	-12.53	-12.57	-14.00	-12.96	-13.07	-14.34	
UMTS	12.2 kbps AMR	-13.59	-14.33	-13.68	-13.57	-13.56	-13.42	-13.88	-13.61	-13.92	
	HSUPA Subtest1	-23.74	-23.60	-23.63	-23.78	-23.94	-23.56	-23.81	-23.62	-23.49	

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
71	680.5	133297	20	16QAM	1	0	-9.14
12	707.5	23095	10	16QAM	1	0	-9.98
13	782.0	23230	10	16QAM	1	0	-9.43
14	793.0	23330	10	16QAM	1	0	-10.35
26	831.5	26865	15	16QAM	1	0	-10.02
5	836.5	20525	10	16QAM	1	0	-10.00
66	1745.0	132322	20	16QAM	1	0	-9.92
2	1880.0	18900	20	16QAM	1	0	-10.10
25	1882.5	26365	20	16QAM	1	0	-9.15
30	2310.0	27710	10	16QAM	1	0	-9.87
7	2535.0	21100	20	16QAM	1	0	-9.62
71	680.5	133297	20	64QAM	1	0	-9.82
71	680.5	133297	20	256QAM	1	0	-9.44
71	680.5	133297	20	QPSK	1	0	-10.31
71	680.5	133297	20	16QAM	1	50	-10.31
71	680.5	133297	20	16QAM	1	99	-10.31
71	680.5	133297	20	16QAM	50	0	-10.31
71	680.5	133297	20	16QAM	100	0	-10.31
71	680.5	133297	15	16QAM	1	0	-9.92
71	680.5	133297	10	16QAM	1	0	-9.89
71	680.5	133297	5	16QAM	1	0	-10.19

 Table 7-4

 LTE FDD Modulation Interference Factors<sup>1,2,3</sup>

 Table 7-5

 LTE FDD Uplink Carrier Aggregation Modulation Interference Factor<sup>1,4</sup>

			PCC									SCC				
	Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL) Channel	PCC (UL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL) Channel	SCC (UL) Frequency [MHz]	Modulation	SCC UL# RB	SCC UL RB Offset	MIF (dB)
	CA_5B	LTE B5	10	20525	836.5	16QAM	1	0	LTE B5	5	20453	829.3	16QAM	1	24	-10.92
	CA_66B	LTE B66	10	132322	1745.0	16QAM	1	0	LTE B66	10	132223	1735.1	16QAM	1	49	-10.96
ĺ	CA_66C	LTE B66	20	132322	1745.0	16QAM	1	0	LTE B66	20	132124	1725.2	16QAM	1	99	-10.98

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup> Note: All FDD LTE bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

<sup>3</sup> Note: Since LTE Band 71 at 20 MHz bandwidth is the overall worst-case LTE MIF and does not support 3 nonoverlapping channels, MIF measurements were made only on the middle channel.

<sup>4</sup> Note: LTE FDD ULCA was evaluated to ensure LTE FDD standalone was the worst-case scenario. The configurations in Table 7-5 were determined from Table 7-4 and satisfy the configuration requirements as defined in 3GPP 36.101.

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LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	-3.42
41	2593.0	40620	20	QPSK	1	0	-3.27
41	2593.0	40620	20	64QAM	1	0	-3.02
41	2593.0	40620	20	256QAM	1	0	-3.10
41	2593.0	40620	20	64QAM	1	50	-3.24
41	2593.0	40620	20	64QAM	1	99	-3.24
41	2593.0	40620	20	64QAM	50	0	-3.22
41	2593.0	40620	20	64QAM	100	0	-3.23
41	2593.0	40620	15	64QAM	1	0	-3.26
41	2593.0	40620	10	64QAM	1	0	-3.26
41	2593.0	40620	5	64QAM	1	0	-3.15
41	2506.0	39750	20	64QAM	1	0	-3.25
41	2549.5	40185	20	64QAM	1	0	-3.30
41	2636.5	41055	20	64QAM	1	0	-3.06
41	2680.0	41490	20	64QAM	1	0	-3.25

 Table 7-6

 LTE TDD B41 Power Class 3 Modulation Interference Factors<sup>1,2</sup>

 Table 7-7

 LTE TDD B41 Power Class 2 Modulation Interference Factors<sup>1,2</sup>

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	-1.57
41	2593.0	40620	20	QPSK	1	0	-1.64
41	2593.0	40620	20	64QAM	1	0	-1.57
41	2593.0	40620	20	256QAM	1	0	-1.55
41	2593.0	40620	20	256QAM	1	50	-1.60
41	2593.0	40620	20	256QAM	1	99	-1.61
41	2593.0	40620	20	256QAM	50	0	-1.65
41	2593.0	40620	20	256QAM	100	0	-1.66
41	2593.0	40620	15	256QAM	1	0	-1.36
41	2593.0	40620	10	256QAM	1	0	-1.34
41	2593.0	40620	5	256QAM	1	0	-1.45
41	2506.0	39750	10	256QAM	1	0	-1.57
41	2549.5	40185	10	256QAM	1	0	-1.52
41	2636.5	41055	10	256QAM	1	0	-1.35
41	2680.0	41490	10	256QAM	1	0	-1.57

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup> Note: LTE TDD MIFs were taken using UL-DL Configuration 0 for Power class 3 LTE TDD and UL-DL configuration 1 for Power class 2 LTE TDD. More information about the chosen UL-DL Configuration can be found in Section 10.

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LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
48	3625.0	55990	20	16QAM	1	0	-3.44
48	3625.0	55990	20	QPSK	1	0	-3.28
48	3625.0	55990	20	64QAM	1	0	-3.24
48	3625.0	55990	20	256QAM	1	0	-3.17
48	3625.0	55990	20	256QAM	1	50	-3.18
48	3625.0	55990	20	256QAM	1	99	-3.18
48	3625.0	55990	20	256QAM	50	0	-3.36
48	3625.0	55990	20	256QAM	100	0	-3.37
48	3625.0	55990	15	256QAM	1	0	-2.99
48	3625.0	55990	10	256QAM	1	0	-2.97
48	3625.0	55990	5	256QAM	1	0	-3.21
48	3555.0	55290	10	256QAM	1	0	-3.02
48	3695.0	56690	10	256QAM	1	0	-3.15

 Table 7-8

 LTE TDD B48 Modulation Interference Factors<sup>1,2</sup>

#### Table 7-9

LTE TDD Uplink Carrier Aggregation Modulation Interference Factor<sup>1,3</sup>

		PCC							SCC						
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL/DL) Channel	PCC (UL/DL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL/DL) Channel	SCC (UL/DL) Frequency [MHz]		SCC UL# RB	SCC UL RB Offset	MIF (dB)
CA_41C (PC3)	LTE B41	20	40620	2593.0	16QAM	1	0	LTE B41	20	40422	2573.2	16QAM	1	99	-3.36
CA_41C (PC2)	LTE B41	20	40620	2593.0	16QAM	1	0	LTE B41	20	40422	2573.2	16QAM	1	99	-1.63
CA_48C	LTE B48	20	55773	2593.0	16QAM	1	0	LTE B48	20	55575	2573.2	16QAM	1	99	-3.11

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup> Note: LTE TDD MIFs were taken using UL-DL Configuration 0 for Power Class 3 LTE TDD. More information about the chosen UL-DL Configuration can be found in Section 10.

<sup>3</sup> Note: LTE TDD ULCA was evaluated to ensure LTE TDD standalone was the worst-case scenario. The configurations in Table 7-9 were determined from Tables 7-6 to 7-8 and satisfy the configuration requirements as defined in 3GPP 36.101. These MIFs were evaluated with UL-DL Configuration 0 for Power Class 3 LTE TDD and UL-DL Configuration 1 for Power Class 2 LTE TDD.

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NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]				
n71	680.5	136100	20	DFT-s-OFDM	16QAM	1	1	-9.78				
n12	707.5	141500	15	DFT-s-OFDM	16QAM	1	1	-9.01				
n5	836.5	167300	20	DFT-s-OFDM	16QAM	1	1	-12.44				
n66	1745.0	349000	40	DFT-s-OFDM	16QAM	1	1	-9.16				
n25	1882.5	376500	40	DFT-s-OFDM	16QAM	1	1	-11.05				
n30	2310.0	462000	10	DFT-s-OFDM	16QAM	1	1	-12.48				
n12	707.5	141500	15	DFT-s-OFDM	π/2-BPSK	1	1	-14.86				
n12	707.5	141500	15	DFT-s-OFDM	QPSK	1	1	-16.95				
n12	707.5	141500	15	DFT-s-OFDM	64QAM	1	1	-11.23				
n12	707.5	141500	15	DFT-s-OFDM	256QAM	1	1	-9.55				
n12	707.5	141500	15	CP-OFDM	QPSK	1	1	-13.38				
n12	707.5	141500	15	CP-OFDM	16QAM	1	1	-9.86				
n12	707.5	141500	15	CP-OFDM	64QAM	1	1	-9.24				
n12	707.5	141500	15	CP-OFDM	256QAM	1	1	-9.66				
n12	707.5	141500	15	DFT-s-OFDM	16QAM	1	40	-10.19				
n12	707.5	141500	15	DFT-s-OFDM	16QAM	1	77	-10.17				
n12	707.5	141500	15	DFT-s-OFDM	16QAM	36	0	-16.05				
n12	707.5	141500	15	DFT-s-OFDM	16QAM	75	0	-20.17				
n12	707.5	141500	10	DFT-s-OFDM	16QAM	1	1	-10.23				
n12	707.5	141500	5	DFT-s-OFDM	16QAM	1	1	-10.17				

## Table 7-10 NR FDD Modulation Interference Factors<sup>1,2,3</sup>

## Table 7-11 NR TDD Band n41 Modulation Interference Factors<sup>1,4</sup>

NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	1	1	1.38
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	1	1	1.38
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	1	1	1.44
n41	2593.0	518598	100	DFT-s-OFDM	64QAM	1	1	1.36
n41	2593.0	518598	100	DFT-s-OFDM	256QAM	1	1	1.30
n41	2593.0	518598	100	CP-OFDM	QPSK	1	1	1.33
n41	2593.0	518598	100	CP-OFDM	16QAM	1	1	1.31
n41	2593.0	518598	100	CP-OFDM	64QAM	1	1	1.29
n41	2593.0	518598	100	CP-OFDM	256QAM	1	1	1.33
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	1	137	1.42
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	1	271	1.42
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	135	0	1.35
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	270	0	1.35
n41	2541.0	508200	90	DFT-s-OFDM	16QAM	1	1	1.43
n41	2536.0	507204	80	DFT-s-OFDM	16QAM	1	1	1.43
n41	2593.0	518598	60	DFT-s-OFDM	16QAM	1	1	1.43
n41	2593.0	518598	50	DFT-s-OFDM	16QAM	1	1	1.43
n41	2567.3	513468	40	DFT-s-OFDM	16QAM	1	1	1.42
n41	2593.0	518598	20	DFT-s-OFDM	16QAM	1	1	1.43

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup> Note: All FDD NR bands were found to have substantially similar MIF values given similar RB, BW, waveform, and modulation configurations.

<sup>3</sup> Note: Since NR FDD Band n12 at 15MHz bandwidth is the overall worst-case FDD NR MIF and does not support 3 nonoverlapping channels, MIF measurements were made only on the middle channel.

<sup>4</sup> Note: Since NR TDD Band n41 at 100MHz bandwidth is the overall worst-case n41 MIF and does not support 3 nonoverlapping channels, MIF measurements were made only on the middle channel.

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	1.11.	I DD Dui							
NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]	
n77	3750.0	650000	100	DFT-s-OFDM	π/2-BPSK	1	1	1.39	
n77	3750.0	650000	100	DFT-s-OFDM	QPSK	1	1	1.36	
n77	3750.0	650000	100	DFT-s-OFDM	16QAM	1	1	1.37	
n77	3750.0	650000	100	DFT-s-OFDM	64QAM	1	1	1.45	
n77	3750.0	650000	100	DFT-s-OFDM	256QAM	1	1	1.39	
n77	3750.0	650000	100	CP-OFDM	16QAM	1	1	1.34	
n77	3750.0	650000	100	CP-OFDM	QPSK	1	1	1.29	
n77	3750.0	650000	100	CP-OFDM	64QAM	1	1	1.33	
n77	3750.0	650000	100	CP-OFDM	256QAM	1	1	1.19	
n77	3750.0	650000	100	DFT-s-OFDM	64QAM	1	137	1.37	
n77	3750.0	650000	100	DFT-s-OFDM	64QAM	1	271	1.37	
n77	3750.0	650000	100	DFT-s-OFDM	64QAM	135	0	1.34	
n77	3750.0	650000	100	DFT-s-OFDM	64QAM	270	0	1.35	
n77	3840.0	656000	90	DFT-s-OFDM	64QAM	1	1	1.38	
n77	3840.0	656000	80	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3805.0	653666	70	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3803.3	653556	60	DFT-s-OFDM	64QAM	1	1	1.36	
n77	3840.0	656000	50	DFT-s-OFDM	64QAM	1	1	1.48	
n77	3816.0	654400	40	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3815.0	654334	30	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3814.0	654266	20	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3725.0	648334	50	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3782.5	652166	50	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3897.5	659834	50	DFT-s-OFDM	64QAM	1	1	1.37	
n77	3955.0	663666	50	DFT-s-OFDM	64QAM	1	1	1.36	

 Table 7-12

 NR TDD Band n77 Modulation Interference Factors<sup>1</sup>

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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	Table 7-13										
80	802.11b (2.4GHz, SISO) Modulation Interference Factors <sup>1,2</sup>										
	802.11b MIF Measurements [dB]										
	Mode		Data Rat	e [Mbps]							
	1 2 5.5 11										
	802.11b	-10.30	-9.56	-7.44	-6.42						

# Table 7-14 802.11g (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

				802.1 <sup>°</sup>	1g MIF Mea	asurement	s [dB]						
Mode Data Rate [Mbps]													
		12	18	24	36	48	72	96	108				
	802.11g	-7.52	-7.52 -6.82 -6.14 -5.51 -5.07 -4.74 -4.92 -4.98										

#### Table 7-15

802.11n (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

	802.11n (2.4GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0	1	2	3	4	5	6	7				
802.11n	-7.44	-7.44 -6.11 -5.44 -5.14 -4.84 -4.90 -5.00 -5.03										

Table	7-16
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802.11ax (2.4GHz, SU, MIMO) Modulation Interference Factors<sup>1,2</sup>

		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]											
Mode	MCS Index												
	0	1	2	3	4	5	6	7	8	9			
802.11ax	-5.92	5.92 -4.87 -4.82 -4.88 -5.03 -5.37 -5.41 -5.57 -5.62 -5.77											

# Table 7-17 802.11ax (2.4GHz, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]									
Mode		RU Index (MCS Index 02) (GI 1.6us)									
	0	0 8 37 40 53 54 61									
802.11ax	-8.11	-8.11 -7.65 -6.75 -6.47 -5.46 -5.30 -4.65									

#### Table 7-18

802.11a (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

	802.11a MIF Measurements [dB]											
Mode		Data Rate [Mbps]										
	12 18 24 36 48 72 92 108											
802.11a	-7.55	-7.55 -6.80 -6.16 -5.49 -5.05 -4.79 -4.94 -5.03										

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup>Note: WIFI MIF values were found to be independent of the transmit channel.

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	802.11n (5GHz, 20MHz BW, MIMO) Modulation Interference Factors <sup>1,2</sup>										
	20MHz BW 802.11n (5GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7									
802.11n	-7.47	-6.17	-5.50	-5.12	-4.82	-4.89	-5.01	-5.12			

 Table 7-19

 802.11n (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

 Table 7-20

 802.11ac (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

			20MHz BV	V 802.11ac	: (5GHz) M	IF Measure	ements [dl	3]			
Mode	MCS Index										
	0 1 2 3 4 5 6 7 8										
802.11ac	-6.23	-5.17	-4.85	-4.86	-5.22	-5.60	-5.72	-5.86	-6.10		

#### Table 7-21

802.11ax (5GHz, 20MHz BW, SU, MIMO) Modulation Interference Factors<sup>1,2</sup>

Mode				20N	1Hz 802.11	ax (5GHz)	MIF Measu	urements [	dB]			
		MCS Index										
	0	1	2	3	4	5	6	7	8	9	10	11
802.11ax	-5.89	-4.96	-4.81	-4.89	-5.12	-5.42	-5.49	-5.66	-5.71	-5.83	-5.90	-6.06

Table 7 00

			Table	<del>)</del> /-ZZ							
802.11ax (5GHz, 20MHz BW, RU, MIMO) Modulation Interference Factors <sup>1,2</sup>											
	20MHz 802.11ax (5GHz) MIF Measurements [dB]										
Mode	Mode RU Index (MCS Index 02) (GI 1.6us)										
	0 8 37 40 53 54 61										
802.11ax	-7.91	-8.02	-6.71	-6.70	-5.46	-5.49	-4.79				

#### Table 7-23

802.11n (5GHz, 40MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

		40MH	Iz BW 802.	.11n (5GHz	z) MIF Mea	surements	[dB]				
Mode	Mode         MCS Index           0         1         2         3         4         5         6         7										
802.11n	-5.91	-5.91 -4.87 -4.65 -4.79 -5.26 -5.74 -5.91 -6.09									

#### Table 7-24

802.11ac (5GHz, 40MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

			asuremen	ts [dB]							
Mode	MCS Index										
	0 1 2 3 4 5 6 7 8 9										
802.11ac	-4.91	-4.75	-5.16	-5.60	-6.10	-6.60	-6.75	-6.91	N/A	-7.20	

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-25
802.11ax (5GHz, 40MHz BW, SU, MIMO) Modulation Interference Factors <sup>1,2</sup>

				40N	IHz 802.11	ax (5GHz)	MIF Measu	urements [	dB]			
Mode		MCS Index										
	0	1	2	3	4	5	6	7	8	9	10	11
802.11ax	-4.71	-4.74	-5.00	-5.32	-5.64	-5.94	-6.06	-6.12	-6.37	-6.37	-6.35	-6.35

# Table 7-26 802.11ax (5GHz, 40MHz BW, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

	40MHz 802.11ax (5GHz) MIF Measurements [dB]								
Mode	Mode RU Index (MCS Index 02) (GI 1.6us)								
	0	17	37	44	53	56	61	62	65
802.11ax	-9.35	-9.51	-8.69	-8.54	-7.35	-7.36	-5.82	-5.85	-4.76

	Та	able	7-27
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#### 802.11ac (5GHz, 80MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

		80MHz BW 802.11ac (5GHz) MIF Measurements [dB]								
Mode	MCS Index									
	0 1 2 3 4 5 6 7 8 9								9	
802.11ac	-4.82	-5.64	-6.14	-6.53	-6.95	-7.25	-7.25	-7.41	-7.42	-7.57

# Table 7-28 802.11ax (5GHz, 80MHz BW, SU, MIMO) Modulation Interference Factors<sup>1,2</sup> 80MHz 802.11ax (5GHz) MIF Measurements [dB]

		80MHz 802.11ax (5GHz) MIF Measurements [dB]										
Mode		MCS Index										
	0	1	2	3	4	5	6	7	8	9	10	11
802.11ax	-4.73	-5.39	-5.71	-6.02	-6.18	-6.45	-6.43	-6.45	-6.67	-6.68	-6.68	-6.68

### Table 7-29

802.11ax (5GHz, 80MHz BW, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

		80MHz 802.11ax (5GHz) MIF Measurements [dB]									
Mode		RU Index (MCS Index 00) (GI 1.6us)									
	0 36 37 52 53 60 61 64 65 66 67								67		
802.11ax	-9.31	-9.48	-8.66	-8.49	-7.31	-7.33	-5.77	-5.82	-4.76	-4.71	-4.69

		Table 7-30								
	802.11ac (5GHz, 160MHz BW, MIMO) Modulation Interference Factors <sup>1,2</sup>									
		160MHz BW 802.11ac (5GHz) MIF Measurements [dB]								
Mode	MCS Index									
	0	0 1 2 3 4 5 6 7 8 9								
802.11ac	-5.60	-6.52	-6.97	-7.27	-7.43	-7.58	-7.60	-7.81	-7.78	-7.77

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

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	80	802.11ax (5GHZ, 160MHZ BW, SU, MIMO) Modulation Interference Factors **										
	160MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0 1 2 3 4 5 6 7 8 9 10 11											
802.11ax	-5.33	-5.98	-6.16	-6.42	-6.51	-6.66	-6.65	-6.65	-6.67	-6.67	-6.82	-6.81

Table 7-31

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Simultaneous	2.4GHz ar		l <b>e 7-32</b> /IFI Modula	tion Interfe	rence Factors <sup>1,2,3</sup>
# T~		5 GHz WFI 2.4 GHz WFI			
Тх	Ant1	Ant2	Ant1	Ant2	
3	х	х	х	-	-5.72
3	х	х	-	х	-5.72

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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<sup>2</sup> Note: WLAN MIF values were found to be independent of the transmit channel.

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<sup>3</sup>Note: The configuration for each scenario (e.g. bandwidth, data rate, etc.) was determined using the worst-case configuration from SISO and MIMO MIF measurements.

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## 8. RF CONDUCTED POWER MEASUREMENTS

### I. Procedures Used to Establish RF Signal for HAC Testing

The handset was configured to transmit the required air interface in a shielded chamber. Measurements were taken with a fully charged battery.

### **II. HAC Measurement Conditions**

#### **Output Power Verification**

Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces for which full testing scans are required. Modes which are exempted from full testing according to Section 9 of this report have only their conducted power targets listed below, not measured values. See Table 8-1 for air interface specific settings of transmit power parameters. See Table 9-1 for more information regarding which modes required full testing and had conducted power measurements taken.

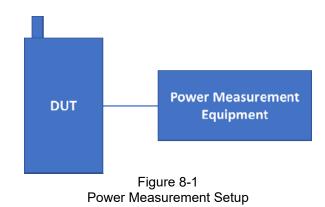
Power Co	Power Control Parameters and Settings by Air Interface									
Air Interface:	Parameter Name:	Parameter Set To:								
CDMA	Power Control Bits	"All Up"								
GSM	PCL	GSM850: "5"; GSM1900: "0"								
UMTS	TPC	"All 1's"								
LTE TPC		"Max Power"								
NR	PLS	Mfr Specified								
WIFI	PLS	Mfr Specified								

 Table 8-1

 Power Control Parameters and Settings by Air Interface

#### III. Setup Used to Measure RF Conducted Powers

The general setup for conducted power is shown in Figure 8-1 below. The power measurement equipment could be a base station simulator, signal analyzer, or power meter depending on the applicable air interface.



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Band	Channel	Rule Part	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO75 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]	1x EvDO Rev. A [dBm]
	F-RC		MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4	(RETAP)
Cellular	564	90S	820.1	24.55	24.56	24.56	24.55	24.55	24.61	24.55	24.56	24.55	24.55	24.56	24.58
	1013	22H	824.7	24.67	24.66	24.66	24.65	24.67	24.71	24.67	24.66	24.65	24.67	24.67	24.60
Cellular	384	22H	836.52	24.46	24.44	24.45	24.45	24.45	24.63	24.45	24.46	24.46	24.46	24.47	24.43
	777	22H	848.31	24.52	24.51	24.50	24.51	24.51	24.64	24.51	24.50	24.51	24.50	24.49	24.48
	25	24E	1851.25	23.29	23.28	23.29	23.29	23.27	23.42	23.29	23.28	23.28	23.29	23.30	23.26
PCS	600	24E	1880	23.42	23.36	23.37	23.34	23.36	23.41	23.35	23.32	23.34	23.34	23.35	23.20
	1175	24E	1908.75	23.16	23.17	23.16	23.16	23.15	23.43	23.17	23.17	23.16	23.17	23.17	22.98

## **IV. CDMA Conducted Powers**

## V. GSM Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)	EDGE [dBm] 1 Tx Slot
	128	32.48	26.73
GSM 850	190	32.17	26.70
	251	32.33	26.53
	512	29.10	25.19
GSM 1900	661	28.93	25.38
	810	29.15	25.75

## **VI. UMTS Target Powers**

Table 8-2 UMTS Conducted Power Targets						
		Mc	dulated Av	verage (dE	3m)	
Mode / Band		3GPP WCDMA	3GPP HSDPA	3GPP HSUPA	3GPP DC- HSDPA	
UMTS Band 5 (850 MHz)	Maximum	25.5	24.5	24.5	24.5	
010113 Ballu 5 (850 10172)	Nominal	24.5	23.5	23.5	23.5	
LINATE Dand 4 (17EO MUT)	Maximum	24.0	23.0	23.0	23.0	
UMTS Band 4 (1750 MHz)	Nominal	23.0	22.0	22.0	22.0	
LINATS Rand 2 (1000 MHz)	Maximum	24.0	23.0	23.0	23.0	
UMTS Band 2 (1900 MHz)	Nominal	23.0	22.0	22.0	22.0	

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## VII. LTE FDD Target Powers

LTE FDD Conducted Power Targets						
Mode / Ban	ч	Modulated Average				
WOUE / Dall	(dBm)					
LTE Band 71	Maximum	25.8				
LIE Dallu / I	Nominal	24.8				
LTE Band 12	Maximum	25.8				
LIE Dallu 12	Nominal	24.8				
LTE Band 13	Maximum	25.8				
LIE Dallu 15	Nominal	24.8				
LTE Band 14	Maximum	25.8				
LIE Dallu 14	Nominal	24.8				
LTE Dand 26 (Call)	Maximum	25.8				
LTE Band 26 (Cell)	Nominal	24.8				
LTE Dand E (Call)	Maximum	25.8				
LTE Band 5 (Cell)	Nominal	24.8				
LTE Dand CC (ANA/C)	Maximum	24.0				
LTE Band 66 (AWS)	Nominal	23.0				
LTE Dand 4 (A)A(C)	Maximum	24.0				
LTE Band 4 (AWS)	Nominal	23.0				
LTE Dand 2E (DCC)	Maximum	24.5				
LTE Band 25 (PCS)	Nominal	23.5				
TE Dand 2 (DCC)	Maximum	24.5				
LTE Band 2 (PCS)	Nominal	23.5				
LTE Dand 20	Maximum	24.0				
LTE Band 30	Nominal	23.0				
LTE David 7	Maximum	24.0				
LTE Band 7	Nominal	23.0				

Table 8-3 LTE FDD Conducted Power Targe

## Table 8-4 LTE FDD Uplink Carrier Aggregation Conducted Power Targets

Mode / Band	Modulated Average (dBm)	
LTE Band 5 (Cell)	Maximum	25.8
LTE Ballu 5 (Cell)	Nominal	24.8
LTE Dond CC (ANAC)	Maximum	24.0
LTE Band 66 (AWS)	Nominal	23.0

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## VIII. LTE TDD Target Powers

Table 8-5 LTE TDD Conducted Power Targets				
Mode / Banc	Modulated Average (dBm)			
LTE Band 48	Maximum	24.5		
LTE Band 48	Nominal	23.5		
ITE Dand (11 (DC2)	Maximum	25.0		
LTE Band 41 (PC3)	Nominal	24.0		
LTE Dand 41 (DC2)	Maximum	27.5		
LTE Band 41 (PC2)	Nominal	26.5		
	Maximum	25.0		
LTE Band 38	Nominal	24.0		

## Table 8-6

## LTE TDD Uplink Carrier Aggregation Conducted Powers

Mode / Banc	Modulated Average (dBm)	
LTE Band 48	Maximum	24.5
LTE Ballu 48	Nominal	23.5
LTE Band 41 (PC3)	Maximum	25.0
LTE Ballu 41 (FCS)	Nominal	24.0
LTE Dand 41 (DC2)	Maximum	27.5
LTE Band 41 (PC2)	Nominal	26.5

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## **IX. NR FDD Target Powers**

NR FDD Conducted Power Targets					
Mode / Pap	Mode / Band				
WOUE / Dall	(dBm)				
NR n71	Maximum	25.5			
	Nominal	24.5			
NR n12	Maximum	25.5			
	Nominal	24.5			
NR n5	Maximum	25.5			
	Nominal	24.5			
NR n66 (Ant A)	Maximum	24.8			
NK 1100 (AIIL A)	Nominal	23.8			
NR n66 (Ant E)	Maximum	24.5			
NK 100 (Allt E)	Nominal	23.5			
ND $p 2E (Apt A)$	Maximum	24.8			
NR n25 (Ant A)	Nominal	23.8			
	Maximum	24.5			
NR n25 (Ant E)	Nominal	23.5			
NR n2 (Ant A)	Maximum	24.8			
	Nominal	23.8			
ND p2 (Apt E)	Maximum	24.5			
NR n2 (Ant E)	Nominal	23.5			
ND p20	Maximum	24.0			
NR n30	Nominal	23.0			

#### Table 8-7 NR EDD Conducted Power Targets

## X. NR TDD Target Powers

Table 8-8 NR TDD Conducted Power Targets

Mode / Band	Modulated Average	
Wode / Banc	(dBm)	
NR n41 - PC3 (Ant B)	Maximum	25.0
NK 1141 - PC5 (AIIL B)	Nominal	24.0
NR n41 - PC3 (Ant E)	Maximum	25.0
NK 1141 - PC5 (Ant E)	Nominal	24.0
NR n41 - PC2 (Ant E)	Maximum	27.0
NK 1141 - PC2 (Ant E)	Nominal	26.0
NR n77 (PC3)	Maximum	24.5
INT II// (PCS)	Nominal	23.5
NR n77 (PC2)	Maximum	26.5
NIX 1177 (PC2)	Nominal	25.5

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## XI. WIFI Target Powers (SISO/MIMO)

		IEEE 802.11 (in dBm)								
		SISO								
Mode	Band	Antenna 1 & Antenna 2	МІМО					МІМО		
		b	g (CDD + STBC)	n (CDD + STBC, SDM)	ax (SU) (CDD + STBC, SDM)					
2.4 GHz					19.0					
WIFI	2 45 GHz	16.0	19.0	19.0	ch. 1: 17.0					
					ch. 11: 17.5					

 Table 8-9

 2.4GHz IEEE 802.11b/g/n/ax (SU) Reduced Average RF Power Targets<sup>1</sup>

(Upper tolerance: target +1.0dB)

<u>əGHZ</u>		EE 802.11a/n/ac/ax (SU) Reduced Average RF Power Targets						
			IEEE 802.1	1 (in dBm)				
Mode	Band	МІМО						
		a (CDD + STBC)	n (CDD + STBC, SDM)	ac (CDD + STBC, SDM)	ax (SU) (CDD + STBC, SDM)			
	5200 MHz	16.0	16.0	16.0	16.0			
5 GHz WIFI	5300 MHz	16.0	16.0	16.0	16.0			
(20MHz BW)	5500 MHz	16.0	16.0	16.0	16.0			
	5800 MHz	16.0	16.0	16.0	16.0			
	5200 MHz		16.0	16.0	16.0			
5 GHz WIFI	5300 MHz		16.0	16.0	16.0			
(40MHz BW)	5500 MHz		16.0	16.0	16.0			
	5800 MHz		16.0	16.0	16.0			
	5200 MHz			16.0	16.0			
5 GHz WIFI	5300 MHz			16.0	16.0			
(80MHz BW)	5500 MHz			16.0	16.0			
	5800 MHz			16.0	16.0			
5 GHz WIFI	5250 MHz			15.0	15.0			
(160MHz BW)	5570 MHz			16.0	16.0			

 Table 8-10

 5GHz IEEE 802.11a/n/ac/ax (SU) Reduced Average RF Power Targets<sup>1</sup>

(Upper tolerance: target +1.0dB)

<sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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## XII. WIFI Target Powers for IEEE 802.11ax RU (MIMO)

IEEE 8	Table 8-11 IEEE 802.11ax (RU) Reduced Average RF Power Targets <sup>1</sup>						
Tones	2.4GHz	5GHz/20MHz	MIMO (ALL) /in dBm				
	2.4GHZ	5GHZ/20MHZ	5GHz/40MHz	5GHz/80MHz	5GHz/160MHz		
26T	12.5	9	9	9	8		
52T	15	12	12	12	12		
106T	15	15	15	14	14		
242T	16	16	15	14	14		
484T			16	14	14		
996T				16	14		
	(	Upper toleran	ce: target +1.0	dB)			

<sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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## XIII. WIFI Target Powers for Operations with Simultaneous 2.4GHz and 5GHz

			IEEE 802.11 (in dBm)				
		SISO	МІМО				
Mode	Band	Antenna 1 & Antenna 2					
		b	g (CDD + STBC)	n (CDD + STBC, SDM)	ax (SU) (CDD + STBC, SDM)		
2.4 GHz WIFI	2.45 GHz	13.0	16.0	16.0	16.0		

Table 8-12

2.4GHz IEEE 802.11b/g/n/ax (SU) Reduced Average RF Power Targets<sup>1</sup>

(Upper tolerance: target +1.0dB)

<u>5GHz I</u>	z IEEE 802.11a/n/ac/ax (SU) Reduced Average RF Power Targets <sup>1</sup>						
				1 (in dBm) MO			
Mode	Band		WII				
		a (CDD + STBC)	n (CDD + STBC, SDM)	ac (CDD + STBC, SDM)	ax (SU) (CDD + STBC, SDM)		
	5200 MHz	16.0	16.0	16.0	16.0		
5 GHz WIFI	5300 MHz	16.0	16.0	16.0	16.0		
(20MHz BW)	5500 MHz	16.0	16.0	16.0	16.0		
	5800 MHz	16.0	16.0	16.0	16.0		
	5200 MHz		16.0	16.0	16.0		
5 GHz WIFI	5300 MHz		16.0	16.0	16.0		
(40MHz BW)	5500 MHz		16.0	16.0	16.0		
	5800 MHz		16.0	16.0	16.0		
	5200 MHz			16.0	16.0		
5 GHz WIFI	5300 MHz			16.0	16.0		
(80MHz BW)	5500 MHz			16.0	16.0		
	5800 MHz			16.0	16.0		
5 GHz WIFI	5250 MHz			15.0	15.0		
(160MHz BW)	5570 MHz			16.0	16.0		

 Table 8-13

 5GHz IEEE 802.11a/n/ac/ax (SU) Reduced Average RF Power Targets<sup>1</sup>

(Upper tolerance: target +1.0dB)

<sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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# XIV. WIFI Target Powers for IEEE 802.11ax RU Operations with Simultaneous 2.4GHz and 5GHz

IEEE 802.11ax (RU) Reduced Average RF Power Targets <sup>1</sup>							
Tones		n	MIMO (ALL) /in dBm	r			
10100	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	5GHz/160MHz		
26T	12.5	9	9	9	8		
52T	15	12	12	12	12		
106T	15	15	15	14	14		
242T	16	16	15	14	14		
484T			16	14	14		
996T				16	14		
-		Linner teleren	ce: target +1.0				

Table 8-14 EE 802.11ax (RU) Reduced Average RF Power Targets<sup>1</sup>

(Upper tolerance: target +1.0dB)

<sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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#### JUSTIFICATION OF HELD TO EAR MODES TESTED 9.

## I. Analysis of RF Air Interface Technologies

An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst-case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst-case MIF plus the worst-case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

Table 9-1

Max Power + MIF calculati	ons for Low	Power Ex	emptions	;
Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
CDMA - Full Frame Rate	24.65	-19.58	5.07	No
CDMA - 1/8 <sup>th</sup> Frame Rate	15.62*	3.11	18.73	Yes
CDMA - EvDO	24.60	-18.84	5.76	No
GSM - GSM850	23.29*	3.56	26.85	Yes
GSM - GSM1900	19.96*	3.55	23.51	Yes
GSM - EDGE850	17.54*	3.73	21.27	Yes**
GSM - EDGE1900	16.56*	3.76	20.32	Yes**
UMTS - RMC	25.50	-12.53	12.97	No
UMTS - AMR	25.50	-13.42	12.08	No
UMTS - HSPA	24.50	-23.49	1.01	No
LTE FDD	25.80	-9.14	16.66	No
LTE FDD - Uplink Carrier Aggregation	25.80	-10.92	14.88	No
LTE TDD - Band 41 (PC3)	22.88*	-3.02	19.86	Yes
LTE TDD - Band 41 (PC2)	23.66*	-1.34	22.32	Yes
LTE TDD - Band 48	22.88*	-2.97	19.91	Yes
LTE TDD - Uplink Carrier Aggregation	23.66*	-1.63	22.03	Yes****
NR FDD	25.50	-9.01	16.49	No
NR TDD n41 (PC3)	18.98*	1.44	20.42	Yes
NR TDD n41 (PC2)	20.98*	1.44	22.42	Yes
NR TDD n77 (PC3)	18.48*	1.48	19.96	Yes****
NR TDD n77 (PC2)	20.48*	1.48	21.96	Yes
WIFI - 2.4GHz	20.00	-4.69	15.31	No
WIFI - 5GHz	17.00	-4.59	12.41	No
Simultaneous 2.4GHz and 5GHz WIFI Operations	20.01***	-5.14	14.87	No

## II. Individual Mode Evaluations

\* Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.

\*\* Note: EDGE data modes were considered but not tested as GSM voice modes were found to be the worst-case modes for the GSM air interface.

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\*\*\* Note: This value is calculated as the linear sum of the worst-case power for each band and antenna combination while in simultaneous 2.4GHz and 5GHz operation. This calculation is conservative and for use in this investigation only.

\*\*\*\* Note: LTD TDD Uplink Carrier Aggregation data modes were considered but not tested as LTE TDD standalone modes were found to be the worst-case modes for the LTE TDD air interface.

\*\*\*\*\*Note: NR n77 (PC3) was considered but not tested as NR n77 (PC3) and NR n77 (PC2) operate at the same duty cycle and transmit on the same antenna.

## **III. Low-Power Exemption Conclusions**

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for GSM/CDMA 1/8<sup>th</sup> Frame Rate voice modes as well as LTE TDD (Power Class 3 and Power Class 2) and NR TDD (Power Class 3 and Power Class 2) data modes. All other air interfaces are exempt.

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# **10. LTE TDD UPLINK-DOWNLINK CONFIGURATION**

## I. Uplink-Downlink Configuration Additional Testing

Additional testing was performed on each supported power class for LTE TDD to determine the worst-case Uplink-Downlink configuration for RFE testing.

Per 3GPP TS 36.211, the total frame length for each TDD radio frame of length  $T_f = 307200 \cdot T_s = 10$  ms, where  $T_s$  is a number of time units equal to  $1/(15000 \times 2048)$  seconds. Additionally, each radio frame consists of 10 subframes, each of length  $30720 \cdot T_s = 1$  ms, and subframes can be designated as uplink (U), downlink (D), or special subframe (S), depending on the Uplink-Downlink configuration as indicated in Table 4.2-2 of 3GPP TS 36.211. In the transmission duty factor calculation, the special subframe configuration with the shortest UpPTS duration within the special subframe is used and will be applied for measurement. From 3GPP TS 36.211 Table 4.2-1, the shortest UpPTS is 2192  $\cdot$  Ts which occurs in the normal cyclic prefix and special subframe configuration 4.

See table below outlining the calculated transmission duty cycles for each Uplink-Downlink configuration:

Uplink-downlink	Downlink-to-Uplink	Subframe number										Calculated Transmission
configuration	Switch-point periodicity	0	1	2	3	4	5	6	7	8	9	Duty Cycle (%)
0	5 ms	D	S	υ	υ	U	D	S	U	U	υ	61.4%
1	5 ms	D	S	υ	υ	D	D	S	υ	U	D	41.4%
2	5 ms	D	S	U	D	D	D	S	U	D	D	21.4%
3	10 ms	D	S	υ	υ	U	D	D	D	D	D	30.7%
4	10 ms	D	S	U	U	D	D	D	D	D	D	20.7%
5	10 ms	D	S	U	D	D	D	D	D	D	D	10.7%
6	5 ms	D	S	U	U	U	D	S	U	U	D	51.4%

 Table 10-1

 Uplink-Downlink Configurations for Type 2 Frame Structures

# II. Power Class 3 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 3, all configurations (0-6) are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-2 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-6 and 7-8.

Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.		RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ons														
	20	40620	0	16QAM	1	0	Acoustic	12.28	21.78	-3.02	18.76	35.00	-16.24	M4	2,3,6
	20	40620	1	16QAM	1	0	Acoustic	9.59	19.64	-1.59	18.05	35.00	-16.95	M4	2,3,6
	20	40620	2	16QAM	1	0	Acoustic	6.77	16.61	1.55	18.16	35.00	-16.84	M4	1,2,3
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	8.33	18.41	-1.39	17.02	35.00	-17.98	M4	2,3,6
	20	40620	4	16QAM	1	0	Acoustic	7.30	17.27	0.75	18.02	35.00	-16.98	M4	2,3,6
	20	40620	5	16QAM	1	0	Acoustic	5.37	14.60	3.66	18.26	35.00	-16.74	M4	2,3,6
	20	40620	6	16QAM	1	0	Acoustic	10.92	20.76	-2.50	18.26	35.00	-16.74	M4	2,3,6

 Table 10-2

 LTE TDD Power Class 3 UL-DL Configuration Results

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# III. Power Class 2 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 2, only configurations 1-5 are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-3 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-7.

				TE	TDD	Pow	ver Clas	s 2 UL-	-DL Cor	nfigurat	ion Res	ults			
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ons														
	20	40620	1	16QAM	1	0	Acoustic	14.73	23.36	-1.58	21.78	35.00	-13.22	M4	2,3,6
	20	40620	2	16QAM	1	0	Acoustic	10.09	20.08	1.58	21.66	35.00	-13.34	M4	2,3,6
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	12.38	21.85	-1.38	20.47	35.00	-14.53	M4	2.3.6
	20	40620	4	16QAM	1	0	Acoustic	10.16	20.14	0.78	20.92	35.00	-14.08	M4	2,3,6
	20	40620	5	16QAM	1	0	Acoustic	7.18	17.12	3.75	20.87	35.00	-14.13	M4	2,3,6

Table 10-3
LTE TDD Power Class 2 UL-DL Configuration Results

## **IV. Conclusion**

Per the results above, UL-DL Configuration 0 was used for LTE TDD Power Class 3 and UL-DL configuration 1 was used for LTE TDD Power Class 2 testing.

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# 11. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSMG998U
S/N:	0246M, 0766M, 3972S

## I. E-FIELD EMISSIONS:

HAC Data Summary for E-field - CDMA												
Channel	RC/SO	Device SN	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
ons												
564*	RC1/SO3	0246M	Acoustic	24.55	12.65	22.04	3.08	25.12	45.00	-19.88	M4	7,8,9
1013	RC1/SO3	0246M	Acoustic	24.65	11.34	21.09	3.11	24.20	45.00	-20.80	M4	7,8,9
384	RC1/SO3	0246M	Acoustic	24.46	11.36	21.11	3.05	24.16	45.00	-20.84	M4	7,8,9
777	RC1/SO3	0246M	Acoustic	24.51	10.42	20.36	3.07	23.43	45.00	-21.57	M4	7,8,9
25	RC1/SO3	0246M	Acoustic	23.28	6.08	15.68	3.07	18.75	35.00	-16.25	M4	1,2,3
600	RC1/SO3	0246M	Acoustic	23.34	5.26	14.42	3.07	17.49	35.00	-17.51	M4	1,2,3
1175	RC1/SO3	0246M	Acoustic	23.16	5.10	14.14	3.04	17.18	35.00	-17.82	M4	1,2,3
	ns 564* 1013 384 7777 25 600	ns 564* RC1/SO3 1013 RC1/SO3 384 RC1/SO3 777 RC1/SO3 25 RC1/SO3 600 RC1/SO3	ns 564* RC1/SO3 0246M 1013 RC1/SO3 0246M 384 RC1/SO3 0246M 777 RC1/SO3 0246M 25 RC1/SO3 0246M 600 RC1/SO3 0246M	Channel         RC/SO         Device SN         Scan Center           ns         564*         RC1/SO3         0246M         Acoustic           1013         RC1/SO3         0246M         Acoustic           384         RC1/SO3         0246M         Acoustic           777         RC1/SO3         0246M         Acoustic           25         RC1/SO3         0246M         Acoustic           600         RC1/SO3         0246M         Acoustic	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)           ns         564*         RC1/SO3         0246M         Acoustic         24.55           1013         RC1/SO3         0246M         Acoustic         24.65           384         RC1/SO3         0246M         Acoustic         24.46           777         RC1/SO3         0246M         Acoustic         24.51           25         RC1/SO3         0246M         Acoustic         23.28           600         RC1/SO3         0246M         Acoustic         23.34	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)           564*         RC1/SO3         0246M         Acoustic         24.55         12.65           1013         RC1/SO3         0246M         Acoustic         24.65         11.34           384         RC1/SO3         0246M         Acoustic         24.46         11.36           777         RC1/SO3         0246M         Acoustic         24.51         10.42           25         RC1/SO3         0246M         Acoustic         23.28         6.08           600         RC1/SO3         0246M         Acoustic         23.34         5.26	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)         Time Avg. Field [dB(V/m)]           ns           564*         RC1/SO3         0246M         Acoustic         24.55         12.65         22.04           1013         RC1/SO3         0246M         Acoustic         24.65         11.34         21.09           384         RC1/SO3         0246M         Acoustic         24.46         11.36         21.11           777         RC1/SO3         0246M         Acoustic         24.51         10.42         20.36           25         RC1/SO3         0246M         Acoustic         23.28         6.08         15.68           600         RC1/SO3         0246M         Acoustic         23.34         5.26         14.42	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)         Time Avg. Field [dB(V/m]]         MiF (dB)           ns         564*         RC1/SO3         0246M         Acoustic         24.55         12.65         22.04         3.08           1013         RC1/SO3         0246M         Acoustic         24.65         11.34         21.09         3.11           384         RC1/SO3         0246M         Acoustic         24.46         11.36         21.11         3.05           777         RC1/SO3         0246M         Acoustic         24.51         10.42         20.36         3.07           25         RC1/SO3         0246M         Acoustic         23.28         6.08         15.68         3.07           600         RC1/SO3         0246M         Acoustic         23.34         5.26         14.42         3.07	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)         Time Avg. Field [dB(V/m)]         MIF (dB)         Audio Interference Level [dB(V/m)]           ns           564*         RC1/SO3         0246M         Acoustic         24.55         12.65         22.04         3.08         25.12           1013         RC1/SO3         0246M         Acoustic         24.65         11.34         21.09         3.11         24.20           384         RC1/SO3         0246M         Acoustic         24.46         11.36         21.11         3.05         24.16           777         RC1/SO3         0246M         Acoustic         24.51         10.42         20.36         3.07         23.43           25         RC1/SO3         0246M         Acoustic         23.28         6.08         15.68         3.07         18.75           600         RC1/SO3         0246M         Acoustic         23.34         5.26         14.42         3.07         17.49	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)         Time Avg. Field [dB(V/m]]         MIF (dB)         Audio Interference L(dB)         FCC Limit (dBV/m)           ns         564*         RC1/SO3         0246M         Acoustic         24.55         12.65         22.04         3.08         25.12         45.00           1013         RC1/SO3         0246M         Acoustic         24.65         11.34         21.09         3.11         24.20         45.00           384         RC1/SO3         0246M         Acoustic         24.46         11.36         21.11         3.05         24.16         45.00           7777         RC1/SO3         0246M         Acoustic         24.51         10.42         20.36         3.07         23.43         45.00           25         RC1/SO3         0246M         Acoustic         23.28         6.08         15.68         3.07         18.75         35.00           600         RC1/SO3         0246M         Acoustic         23.34         5.26         14.42         3.07         17.49         35.00	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)         Time Avg. Field (dB(V/m)]         MIF (dB)         Audio Interference (dB)         FCC Limit (dB/m)         FC Limit (dB/m)	Channel         RC/SO         Device SN         Scan Center         Conducted Power at BS (dBm)         Time Avg. Field (V/m)         Time Avg. Field [dB(V/m)]         MiF (dB)         Audio Interference [dB(V/m)]         FCC Limit (dBV/m)         FCC Margin (dB)         Result           564*         RC1/SO3         0246M         Acoustic         24.55         12.65         22.04         3.08         25.12         45.00         -19.88         M4           1013         RC1/SO3         0246M         Acoustic         24.65         11.34         21.09         3.11         24.20         45.00         -20.80         M4           384         RC1/SO3         0246M         Acoustic         24.46         11.36         21.11         3.05         24.16         45.00         -20.80         M4           777         RC1/SO3         0246M         Acoustic         24.51         10.42         20.36         3.07         23.43         45.00         -21.57         M4           777         RC1/SO3         0246M         Acoustic         23.28         6.08         15.68         3.07         18.75         35.00         -16.25         M4           600         RC1/SO3         0246M         Acoustic         23.34         5.26

Table 11-1 HAC Data Summary for E-field - CDMA

\*Note: Cell. CDMA Ch. 564 is the Part 90S test channel.

Table 11-2 HAC Data Summary for E-field - GSM

Mode	Channel	Device SN	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ons											
	128	0246M	Acoustic	32.48	16.15	24.16	3.56	27.72	45.00	-17.28	M4	7,8,9
GSM850	190	0246M	Acoustic	32.17	18.73	25.45	3.56	29.01	45.00	-15.99	M4	7,8,9
	251	0246M	Acoustic	32.33	21.00	26.44	3.55	29.99	45.00	-15.01	M4	7,8,9
	512	0246M	Acoustic	29.10	8.80	18.89	3.53	22.42	35.00	-12.58	M4	1,2,3
GSM1900	661	0246M	Acoustic	28.93	8.11	18.18	3.54	21.72	35.00	-13.28	M4	1,2,3
	810	0246M	Acoustic	29.15	9.47	19.53	3.55	23.08	35.00	-11.92	M4	1,2,3

 Table 11-3

 HAC Data Summary for E-field – LTE TDD Band 41 (Power Class 3)

Mode / Band	Bandwidth (MHz)	Channel	Device SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ons																
	20	39750	0766M	0	64QAM	1	0	Acoustic	21.63	10.48	20.41	-3.25	17.16	35.00	-17.84	M4	1,2,3
	20	40185	0766M	0	64QAM	1	0	Acoustic	21.80	11.09	20.90	-3.30	17.60	35.00	-17.40	M4	2,3,6
LTE TDD / Band 41 PC3	20	40620	0766M	0	64QAM	1	0	Acoustic	21.40	12.28	21.78	-3.02	18.76	35.00	-16.24	M4	2,3,6
	20	41055	0766M	0	64QAM	1	0	Acoustic	21.34	13.03	22.30	-3.06	19.24	35.00	-15.76	M4	2,3,6
	20	41490	0766M	0	64QAM	1	0	Acoustic	21.59	13.55	22.64	-3.25	19.39	35.00	-15.61	M4	2,3,6

	Table 11-4	
HAC Data Summar	y for E-field – LTE TDD Band 41	(Power Class 2)

Mode /		Bandwidth (MHz)	Channel	Device SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
L-1 Iolu I	LIIII33IUI	113	r	r		1						r	r					
		10	39750	0766M	1	256QAM	1	0	Acoustic	22.49	9.28	19.35	-1.57	17.78	35.00	-17.22	M4	2,3,6
		10	40185	0766M	1	256QAM	1	0	Acoustic	22.00	9.55	19.60	-1.52	18.08	35.00	-16.92	M4	2,3,6
LTE T Band 4		10	40620	0766M	1	256QAM	1	0	Acoustic	22.24	9.94	19.95	-1.34	18.61	35.00	-16.39	M4	1,2,3
		10	41055	0766M	1	256QAM	1	0	Acoustic	22.20	12.08	21.64	-1.35	20.29	35.00	-14.71	M4	2,3,6
		10	41490	0766M	1	256QAM	1	0	Acoustic	22.13	10.87	20.72	-1.57	19.15	35.00	-15.85	M4	2,3,6

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Mode / Band	Bandwidth (MHz)	Channel	Device SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ons																
	10	55290	0766M	0	256QAM	1	0	Acoustic	17.96	9.72	19.75	-3.02	16.73	35.00	-18.27	M4	7,8,9
LTE TDD / Band 48	10	55990	0766M	0	256QAM	1	0	Acoustic	17.86	8.67	18.76	-2.97	15.79	35.00	-19.21	M4	4,7,8
	10	56690	0766M	0	256QAM	1	0	Acoustic	18.28	8.25	18.33	-3.15	15.18	35.00	-19.82	M4	4,7,8

Table 11-5HAC Data Summary for E-field – LTE TDD Band 48

 Table 11-6

 HAC Data Summary for E-field – NR TDD Band n41

Mode / Band	Bandwidth (MHz)	Channel	Device SN	Antenna	Waveform	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																
	100	518598	0246M	Ant B - PC3	DFT-s-OFDM	16QAM	1	1	Acoustic	7.73	17.76	1.44	19.20	35.00	-15.80	M4	2,3,6
NR TDD / n41	100	518598	0246M	Ant E - PC2	DFT-s-OFDM	16QAM	1	1	Acoustic	33.36	30.46	1.44	31.90	35.00	-3.10	M3	2,3,6
	100	518598	0246M	Ant E - PC2	DFT-s-OFDM	16QAM	1	1	T-Coil	33.20	30.42	1.44	31.86	35.00	-3.14	M3	3,6,9

Table 11-7

HAC Data Summar	v for E-field – NR	TDD Band n77

Mode / Band	Bandwidth (MHz)	Channel	Device SN	Waveform	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ons															
	50	648334	3972S	DFT-s-OFDM	64QAM	1	1	Acoustic	7.17	17.11	1.37	18.48	35.00	-16.52	M4	7,8,9
	50	652166	3972S	DFT-s-OFDM	64QAM	1	1	Acoustic	7.35	17.32	1.37	18.69	35.00	-16.31	M4	7,8,9
NR TDD / n77	50	656000	3972S	DFT-s-OFDM	64QAM	1	1	Acoustic	5.66	15.05	1.48	16.53	35.00	-18.47	M4	7,8,9
	50	659834	3972S	DFT-s-OFDM	64QAM	1	1	Acoustic	5.89	15.40	1.37	16.77	35.00	-18.23	M4	7,8,9
	50	663666	3972S	DFT-s-OFDM	64QAM	1	1	Acoustic	5.84	15.32	1.36	16.68	35.00	-18.32	M4	7,8,9

# II. Worst-case Configuration Evaluation

 Table 11-8

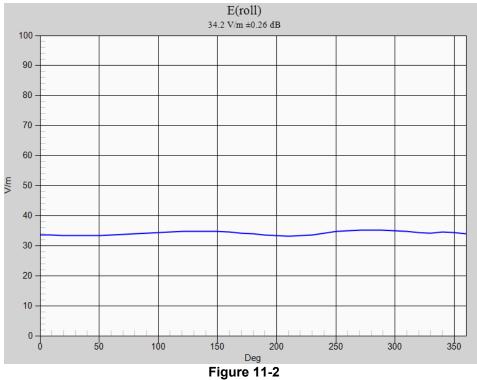
 Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Bandwidth (MHz)	Channel	Device SN	Antenna	Waveform	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
Probe Rotation	n at Worst-Case															
NR TDD / n41	100	518598	0246M	Ant E - PC2	DFT-s-OFDM	16QAM	1	1	Acoustic	30.94	1.44	32.38	35.00	-2.62	M3	2,3,6

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**Figure 11-1** Sample E-field Scan Overlay (See Test Setup Photographs for actual WD overlay)



Worst-Case Probe Rotation about Azimuth axis

\* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

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# 12. EQUIPMENT LIST

## Table 12-1 Equipment List

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4438C	ESG Vector Signal Generator	3/11/2019	Annual	3/11/2021	MY45090700
Agilent	N5182A	MXG Vector Signal Generator	2/19/2020	Annual	2/19/2021	MY47420651
Keysight Technologies	N9020A	MXA Signal Analyzer	12/19/2019	Annual	12/19/2020	MY48010233
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	MA24106A	USB Power Sensor	2/27/2020	Annual	2/27/2021	1244524
Anritsu	MA24106A	USB Power Sensor	6/8/2020	Annual	6/8/2021	1344555
Anritsu	MA2411B	Pulse Power Sensor	12/4/2019	Annual	12/4/2020	1126066
Anritsu	ML2496A	Power Meter	3/23/2020	Annual	3/23/2021	1351001
Control Company	4040	Therm./ Clock/ Humidity Monitor	3/6/2020	Biennial	3/6/2022	200170289
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMW500	Wideband Radio Communication Tester	2/4/2020	Annual	2/4/2021	162125
Rohde & Schwarz	CMW500	Radio Communication Tester	5/21/2020	Annual	5/21/2021	128635
Seekonk	NC-100	Torque Wrench (8" lb)	8/4/2020	Biennial	8/4/2022	N/A
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	EF3DV3	Freespace E-field Probe	1/16/2019	Biennial	1/16/2021	4035
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/19/2019	Biennial	2/19/2021	1003
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/19/2019	Biennial	2/19/2021	1137
SPEAG	CD2600V3	Freespace 2600MHz Dipole	2/19/2019	Biennial	2/19/2021	1012
SPEAG	CD3500V3	Freespace 3500 MHz Dipole	10/20/2020	Biennial	10/20/2022	1005
SPEAG	DAE4	Dasy Data Acquisition Electronics	2/12/2020	Annual	2/12/2021	665

Calibration traceable to the National Institute of Standards and Technology (NIST).

\*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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# **13. MEASUREMENT UNCERTAINTY**

## Table 13-1

Uncertainty Estimation Table

	Wireless Communications Device Near-Field Measurement							
		Uncer	tainty Estima	ation				
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments	
Measurement System	-					-	-	
RF System Reflections	0.50	Tolerance	Ν	1.00	1	0.50	* Refl. < -20 dB	
Field Probe Calibration	0.21	Tolerance	Ν	1.00	1	0.21		
Field Probe Isotropy	0.01	Tolerance	Ν	1.00	1	0.01		
Field Probe Frequency Response	0.135	Tolerance	Ν	1.00	1	0.14		
Field Probe Linearity	0.013	Tolerance	Ν	1.00	1	0.01		
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing	
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*	
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*	
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*	
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*	
Resolution to 2mm error	0.21	Tolerance	Ν	1.00	1	0.21		
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*	
Readout Electronics	0.015	Tolerance	Ν	1.00	1	0.02	*	
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*	
Response Time	0.033	Tolerance	R	1.73	1	0.02	*	
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*	
System Repeatability (Field x 2=power)	0.17	Tolerance	Ν	1.00	1	0.17	*	
Test Sample Related								
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*	
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*	
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*	
Power Drift	0.21	Tolerance	R	1.73	1	0.12		
Combined Standard Uncertainty (k=1)						0.66	16.3%	
Expanded Uncertainty [95% confidence]						1.31	32.6%	
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%	

Notes:

1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.

2. \* Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurements to identify the measurement uncertainty. By combining the repeat measurements with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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# 14. TEST DATA

See following Attached Pages for Test Data.

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### DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

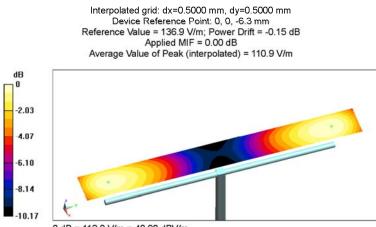
#### **Communication System: CW; Frequency: 835 MHz;**

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## 835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):



0 dB = 112.0 V/m = 40.98 dBV/m

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## DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

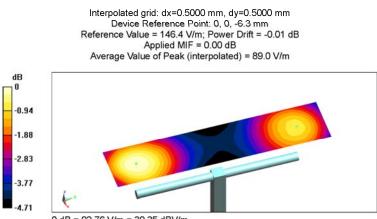
#### **Communication System: CW; Frequency: 1880 MHz;**

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## 1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):



0 dB = 92.76 V/m = 39.35 dBV/m

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## DUT: CD2600V3 - SN1012

Type: CD2600V3 Serial: 1012

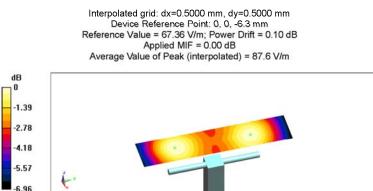
#### **Communication System: CW; Frequency: 2600 MHz;**

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## 2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):



0 dB = 88.08 V/m = 38.90 dBV/m

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## DUT: CD2600V3 - SN1012

Type: CD2600V3 Serial: 1012

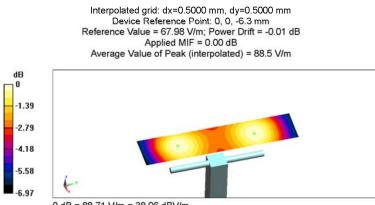
#### **Communication System: CW; Frequency: 2600 MHz;**

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## 2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):



#### 0 dB = 88.71 V/m = 38.96 dBV/m

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## DUT: CD3500V3 - SN1005

Type: CD3500V3 Serial: 1005

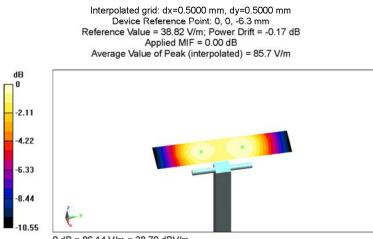
#### Communication System: CW; Frequency: 3500 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## 3500 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):



0 dB = 86.14 V/m = 38.70 dBV/m

#### PCTEST 2020

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Date: 11/16/2020



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## DUT: CD3500V3 - SN1005

Type: CD3500V3 Serial: 1005

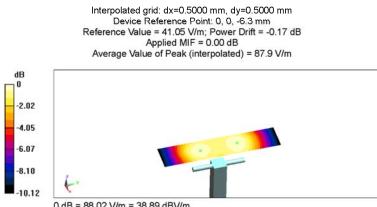
#### Communication System: CW; Frequency: 3500 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## 3500 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):



0 dB = 88.02 V/m = 38.89 dBV/m

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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0246M Backlight off Duty Cycle: 1:8

#### **Communication System: CDMA; Frequency: 820.1 MHz;**

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

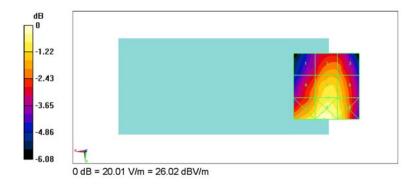
DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### Extended Cell. CDMA Mid Channel /Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 17.10 V/m; Power Drift = 0.10 dB Applied MIF = 3.08 dB RF audio interference level = 25.12 dBV/m Emission category: M4

MIF scaled E-field				
Grid 1 M4	Grid 2 M4	Grid 3 M4		
23.14 dBV/m	24.32 dBV/m	24.18 dBV/m		
Grid 4 M4	Grid 5 M4	Grid 6 M4		
24.14 dBV/m	25.12 dBV/m	24.86 dBV/m		
Grid 7 M4	Grid 8 M4	Grid 9 M4		
25.43 dBV/m	25.91 dBV/m	25.27 dBV/m		



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0246M Backlight off Duty Cycle: 1:8

#### Communication System: CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

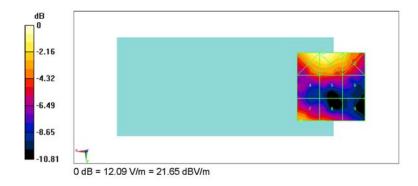
DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### PCS CDMA Low Channel /Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 5.019 V/m; Power Drift = 0.16 dB Applied MIF = 3.07 dB RF audio interference level = 18.75 dBV/m Emission category: M4

MIF scaled E-field				
Grid 1 M4	Grid 2 M4	Grid 3 M4		
21.3 dBV/m	21.52 dBV/m	20.03 dBV/m		
Grid 4 M4	Grid 5 M4	Grid 6 M4		
17.33 dBV/m	17.37 dBV/m	16.53 dBV/m		
Grid 7 M4	Grid 8 M4	Grid 9 M4		
18.75 dBV/m	17.69 dBV/m	15.6 dBV/m		



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0246M Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 848.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

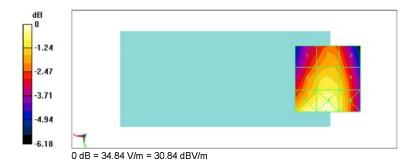
DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### GSM850 High Channel /Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 28.37 V/m; Power Drift = -0.05 dB Applied MIF = 3.55 dB RF audio interference level = 29.99 dBV/m Emission category: M4

MIF scaled E-field				
Grid 1 M4	Grid 2 M4	Grid 3 M4		
28.68 dBV/m	29.24 dBV/m	28.94 dBV/m		
Grid 4 M4	Grid 5 M4	Grid 6 M4		
29.51 dBV/m	29.99 dBV/m	29.67 dBV/m		
Grid 7 M4	Grid 8 M4	Grid 9 M4		
30.63 dBV/m	30.84 dBV/m	30.03 dBV/m		



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0246M Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### GSM1900 High Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 9.018 V/m; Power Drift = -0.10 dB Applied MIF = 3.55 dB RF audio interference level = 23.08 dBV/m Emission category: M4

 MIF scaled E-field

 Grid 1 M4
 Grid 2 M4
 Grid 3 M4

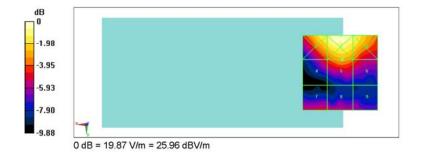
 24.78 dBV/m
 26.01 dBV/m
 25.12 dBV/m

 Grid 4 M4
 Grid 5 M4
 Grid 6 M4

 21.74 dBV/m
 23.08 dBV/m
 22.27 dBV/m

 Grid 7 M4
 Grid 8 M4
 Grid 9 M4

 21.22 dBV/m
 21.18 dBV/m
 20.3 dBV/m



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0766M Backlight off Duty Cycle: 1:1.63

#### Communication System: LTE TDD41; Frequency: 2680 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

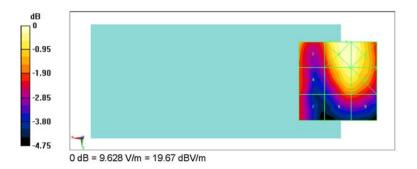
#### TDD LTE Band 41 Power Class 3 High Channel , UL-DL 0, 20MHz, 64QAM, 1RB, 0RB Offset,

Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 15.05 V/m; Power Drift = -0.04 dB Applied MIF = -3.25 dB RF audio interference level = 19.39 dBV/m Emission category: M4

#### MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
18.63 dBV/m	19.67 dBV/m	19.62 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
17.77 dBV/m	19.39 dBV/m	19.38 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
17.51 dBV/m	17.82 dBV/m	17.81 dBV/m



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0766M Backlight off Duty Cycle: 1:2.42

#### Communication System: LTE TDD41; Frequency: 2636.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

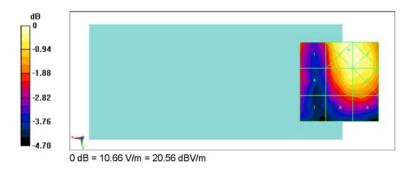
#### TDD LTE Band 41 Power Class 2, Mid High Channel, UL-DL 1, 10MHz, 256QAM, 1RB, 0RB Offset,

Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 13.00 V/m; Power Drift = 0.04 dB Applied MIF = -1.35 dB RF audio interference level = 20.29 dBV/m Emission category: M4

#### MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
18.95 dBV/m	20.55 dBV/m	20.48 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
18.33 dBV/m	20.29 dBV/m	20.3 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
17.68 dBV/m	18.81 dBV/m	18.92 dBV/m



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0766M Backlight off Duty Cycle: 1:1.63

#### Communication System: LTE Band 48; Frequency: 3555 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

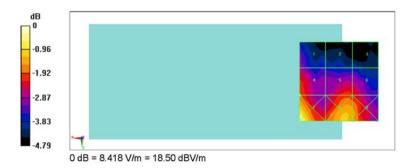
#### TDD LTE Band 48 Low Channel, UL-DL 0, 10MHz, 256QAM, 1RB, 0RB Offset

#### Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 10.60 V/m; Power Drift = -0.01 dB Applied MIF = -3.02 dB RF audio interference level = 16.73 dBV/m Emission category: M4

#### MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
15.69 dBV/m	14.97 dBV/m	14.64 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
16.73 dBV/m	16.46 dBV/m	16.32 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
18.5 dBV/m	17.3 dBV/m	17.07 dBV/m



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 0246M Backlight off Duty Cycle: 1:4

#### Communication System: n41; Frequency: 2593 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

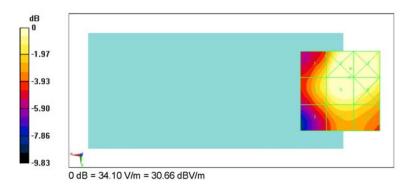
#### NR TDD n41, Ant E - Power Class 2, 100MHz, Mid Channel, DFT-S-OFDM, 16QAM, 1RB, 1RB Offset,

Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 44.51 V/m; Power Drift = 0.00 dB Applied MIF = 1.44 dB RF audio interference level = 31.90 dBV/m Emission category: M3

#### MIF scaled E-field

Grid 1 M4	Grid 2 M3	Grid 3 M3
29.37 dBV/m	32.1 dBV/m	32.01 dBV/m
Grid 4 M4	Grid 5 M3	Grid 6 M3
29.58 dBV/m	31.9 dBV/m	31.79 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
28 dBV/m	29.36 dBV/m	29.2 dBV/m



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## DUT: A3LSMG998U

Type: Portable Handset Serial: 3972S Backlight off Duty Cycle: 1:4

Communication System: n77; Frequency: 3782.49 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

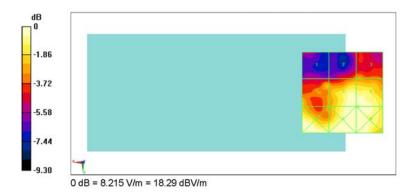
## NR n77 100MHz Low-Mid Channel, DFT-s-OFDM, 64QAM, 1RB, 1RB Offset,

#### Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 8.903 V/m; Power Drift = -0.07 dB Applied MIF = 1.37 dB RF audio interference level = 18.69 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
13.18 dBV/m	15.31 dBV/m	15.51 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
16.16 dBV/m	18.66 dBV/m	18.69 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
19.66 dBV/m	18.85 dBV/m	18.79 dBV/m



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# **15. CALIBRATION CERTIFICATES**

The following pages include the probe calibration used to evaluate HAC for the DUT.

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### Calibration Laboratory of

PC Test

Client

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland



Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Issued: January 17, 2019

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Certificate No:	EE3-4	035	an10
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Object	EF3DV3- SN:4038	5	
Calibration procedure(s)	QA CAL-02.v9, Q/ Calibration proced evaluations in air	A CAL-25.v7 lure for E-field probes optimized f	or close near field /0/H 2/1/12019
Calibration date:	January 16, 2019		2/11/2019
The measurements and the unc	ertainties with confidence pro ucted in the closed laboratory	al standards, which realize the physical units bability are given on the following pages and facility: environment temperature ( $22 \pm 3$ )°C a	are part of the certificate.
Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
	SN: S5277 (20x)	04-Apr-18 (No. 217-02682)	Apr-19
Reference 20 dB Attenuator DAE4	SN: 789	14-Jan-19 (No. DAE4-789_Jan19)	Jan-20
Reference 20 dB Attenuator			
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6	SN: 789 SN: 2328	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18)	Jan-20 Oct-19
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards	SN: 789 SN: 2328	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house)	Jan-20 Oct-19 Scheduled Check
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards Power meter E4419B	SN: 789 SN: 2328 ID SN: GB41293874	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house) 06-Apr-16 (in house check Jun-18)	Jan-20 Oct-19 Scheduled Check In house check: Jun-20
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards	SN: 789 SN: 2328 ID SN: GB41293874 SN: MY41498087	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18)	Jan-20 Oct-19 Scheduled Check In house check: Jun-20 In house check: Jun-20
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards Power meter E4419B Power sensor E4412A	SN: 789 SN: 2328 ID SN: GB41293874	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18)	Jan-20 Oct-19 Scheduled Check In house check: Jun-20 In house check: Jun-20 In house check: Jun-20
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards Power meter E44198 Power sensor E4412A Power sensor E4412A	SN: 769 SN: 2328 ID SN: GB41293874 SN: MY41498087 SN: 000110210	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18)	Jan-20 Oct-19 Scheduled Check In house check: Jun-20 In house check; Jun-20
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards Power meter E4419B Power sensor E4412A Power sensor E4412A RF generator HP 8648C	SN: 789 SN: 2328 ID SN: GB41293874 SN: MY41498087 SN: 000110210 SN: US3642U01700	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18) 04-Aug-99 (in house check Jun-18) 31-Mar-14 (in house check Oct-18)	Jan-20 Oct-19 Scheduled Check In house check: Jun-20 In house check: Jun-20 In house check: Jun-20 In house check: Jun-20 In house check: Oct-19
Reference 20 dB Attenuator DAE4 Reference Probe ER3DV6 Secondary Standards Power meter E4419B Power sensor E4412A Power sensor E4412A RF generator HP 8648C	SN: 789           SN: 2328           ID           SN: GB41293874           SN: MY41498087           SN: 000110210           SN: US3642U01700           SN: US41080477	14-Jan-19 (No. DAE4-789_Jan19) 09-Oct-18 (No. ER3-2328_Oct18) Check Date (in house) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18) 06-Apr-16 (in house check Jun-18) 04-Aug-99 (in house check Jun-18)	Jan-20 Oct-19 Scheduled Check In house check: Jun-20 In house check: Jun-20 In house check: Jun-20 In house check: Jun-20

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#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland



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Accreditation No.: SCS 0108

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### Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C, D	modulation dependent linearization parameters
En	incident E-field orientation normal to probe axis
Ep	incident E-field orientation parallel to probe axis
Polarization φ	φ rotation around probe axis
Polarization 9	$\vartheta$ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

## Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
- b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.1.1, May 2017

## Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization θ = 0 for XY sensors and θ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z \* frequency\_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no
  uncertainty required).

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# DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

### **Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
<u>Norm (μV/(V/m)<sup>2</sup>)</u>	0.90	0.74	1.20	± 10.1 %
DCP (mV) <sup>B</sup>	96.8	98.5	95.3	

### Calibration results for Frequency Response (30 MHz - 6 GHz)

Frequency MHz	Target E-Field V/m	Measured E-field (En) V/m	Deviation E-normal in %	Measured E-field (Ep) V/m	Deviation E-normal in %	Unc (k=2) %
30	77.3	76.8	-0.6%	77.3	0.1%	± 5.1 %
100	77.3	78.2	1.2%	77.8	0.7%	± 5.1 %
450	77.1	78.2	1.5%	77.8	0.9%	± 5.1 %
600	77.1	77.8	0.9%	77.5	0.5%	± 5.1 %
750	77.3	77.7	0.5%	77.2	-0.1%	± 5.1 %
1800	140.3	136.9	-2.4%	137.2	-2.2%	± 5.1 %
2000	133.0	129.4	-2.8%	129.4	-2.7%	± 5.1 %
2200	124.8	121.5	-2.7%	122.7	-1.7%	± 5.1 %
2500	123.7	120.7	-2.4%	121.9	-1.5%	± 5.1 %
3000	78.8	74.8	-5.0%	76.1	-3.5%	± 5.1 %
3500	256.3	248.1	-3.2%	246.0	-4.0%	± 5,1 %
3700	249.7	239.2	-4.2%	239.0	-4.3%	± 5.1 %
5200	50.7	50.7	-0.1%	51.2	0.9%	± 5.1 %
5500	49.6	48.9	-1.5%	48.7	-1.9%	± 5.1 %
5800	48.9	49.1	0.4%	49.3	0.8%	± 5.1 %

## **Calibration Results for Modulation Response**

UID	Communication System Name		A dB	B dBõV	С	D dB	VR mV	Max dev.	Unc <sup>⊨</sup> (k=2)
0	CW	X	0.0	0.0	1.0	0.00	141.5	+ 3.3 %	±4.7 %
		Y	0.0	0.0	1.0		125.6		
		Y	0.0	0.0	1.0		125.1		

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

<sup>B</sup> Numerical linearization parameter: uncertainty not required.
<sup>E</sup> Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the

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EF3DV3 - SN:4035

# DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

## **Sensor Frequency Model Parameters**

	Sensor X	Sensor Y	Sensor Z
Frequency Corr. (LF)	0.28	0.21	5.68
Frequency Corr. (HF)	2.82	2.82	2.82

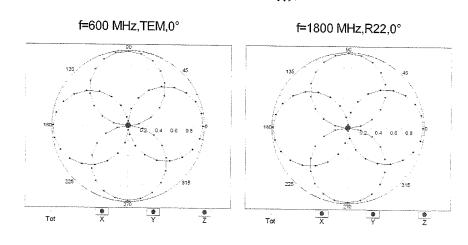
## **Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	57.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	335 mm
Probe Body Diameter	12 mm
Tip Length	25 mm
Tip Diameter	4 mm
Probe Tip to Sensor X Calibration Point	1.5 mm
Probe Tip to Sensor Y Calibration Point	1.5 mm
Probe Tip to Sensor Z Calibration Point	1.5 mm

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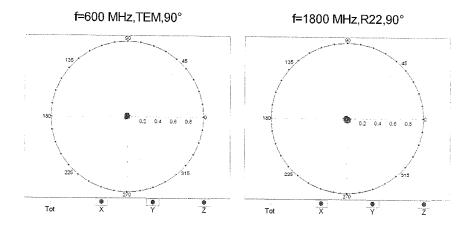
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FCC ID: A3LSMG998U	PCTEST Houd to be part of @ recents	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Receiving Pattern ( $\phi$ ),  $\vartheta = 0^{\circ}$ 

# Receiving Pattern ( $\phi$ ), $\vartheta$ = 90°

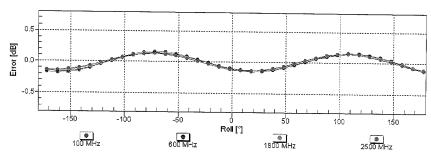


Certificate No: EF3-4035\_Jan19

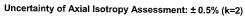
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FCC ID: A3LSMG998U		HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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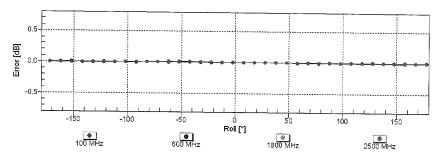
January 16, 2019



# Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Receiving Pattern ( $\phi$ ),  $\vartheta = 90^{\circ}$ 



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

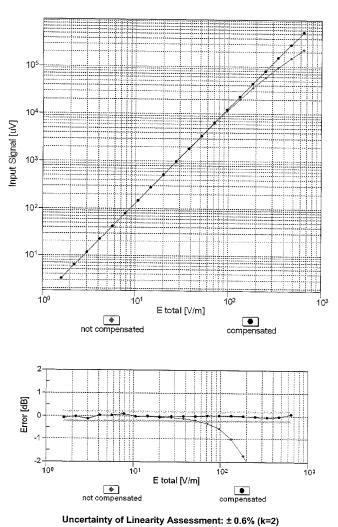
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FCC ID: A3LSMG998U		HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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EF3DV3 - SN:4035

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# Dynamic Range f(E-field) (TEM cell, f = 900 MHz)

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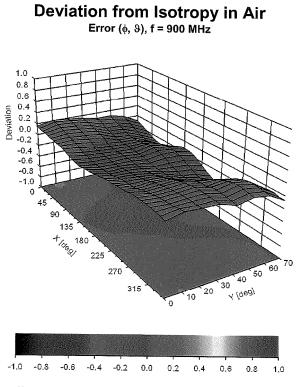
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FCC ID: A3LSMG998U	PCTEST Prost to be port of @ remote	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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EF3DV3 - SN:4035

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Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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Client PC Test

Certificate No: CD835V3-1003\_Feb19

Object	CD835V3 - SN:	1003	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proc	edure for Validation Sources in ai	r /241 3/19/201
Calibration date:	February 19, 20	19	
The measurements and the unc	ertainties with confidence p ucted in the closed laborato	ional standards, which realize the physical un probability are given on the following pages an ry facility: environment temperature (22 $\pm$ 3)°C	d are part of the certificate.
Primary Standards		Col Data (Contificate No.)	
Power meter NRP	SN: 104778	Cal Date (Certificate No.) 04-Apr-18 (No. 217-02672/02673)	Scheduled Calibration
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672) 04-Apr-18 (No. 217-02672)	Apr-19
ower sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: 5058 (20k)		Apr-19
ype-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02682)	Apr-19
Probe EF3DV3	SN: 4013	04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013 Jan19)	Apr-19
DAE4	SN: 781	09-Jan-19 (No. DAE4-781_Jan19)	Jan-20 Jan-20
	ID#	Check Date (in house)	
Secondary Standards		oncon Dato (in nouse)	Scheduled Check
	SN: GB42420191	09-Oct-09 (in house check Oct 17)	In her see also also Oct on
ower meter Agilent 4419B	SN: GB42420191 SN: US38485102	09-Oct-09 (in house check Oct-17) 05- Jan-10 (in house check Oct-17)	In house check: Oct-20
ower meter Agilent 4419B ower sensor HP E4412A	SN: GB42420191 SN: US38485102 SN: US37295597	05-Jan-10 (in house check Oct-17)	In house check: Oct-20
ower meter Agilent 4419B ower sensor HP E4412A ower sensor HP 8482A	SN: US38485102	05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17)	In house check: Oct-20 In house check: Oct-20
ower meter Agilent 4419B ower sensor HP E4412A ower sensor HP 8482A IF generator R&S SMT-06	SN: US38485102 SN: US37295597	05-Jan-10 (in house check Oct-17)	In house check: Oct-20
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: US38485102 SN: US37295597 SN: 832283/011	05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17)	In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-19
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 letwork Analyzer HP 8358A Palibrated by:	SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477	05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18)	In house check: Oct-20 In house check: Oct-20 In house check: Oct-20
ower meter Agilent 4419B ower sensor HP E4412A ower sensor HP 8482A F generator R&S SMT-06 etwork Analyzer HP 8358A	SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477 Name	05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18) Function	In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-19

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Approved by: PCTEST HAC (RF EMISSIONS) TEST REPORT FCC ID: A3LSMG998U (en) SAMSUNG Quality Manager DUT Type: Filename: Test Dates: Page 71 of 100 1M2009230152-20-R2.A3L 10/26/2020 - 11/17/2020 Portable Handset © 2020 PCTEST **REV 3.5.M** 

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#### References

[1]

ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

## Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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#### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum 105.2 V/m = 40.44 dBV/m 105.1 V/m = 40.43 dBV/m	
Maximum measured above high end	100 mW input power		
Maximum measured above low end	100 mW input power		
Averaged maximum above arm	100 mW input power	105.2 V/m ± 12.8 % (k=2)	

# Appendix (Additional assessments outside the scope of SCS 0108)

## **Antenna Parameters**

Frequency	Return Loss	Impedance	
800 MHz	17.6 dB	40.4 Ω - 7.2 jΩ	
835 MHz	25.8 dB	52.2 Ω + 4.7 jΩ	
880 MHz	16.9 dB	62.1 Ω - 10.5 jΩ	
900 MHz	16.9 dB	52.2 Ω - 14.6 jΩ	
945 MHz	21.6 dB	51.8 Ω + 8.3 jΩ	

### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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# Impedance Measurement Plot

10.00	ABSIN			<u>I</u> lace 1	icale M <u>a</u> rke	<u>D</u> yscelli			1	
5.00	ALCONTRACTOR							1:	800.000000 MHz - 825.000000 MHz	-17.586 dB
0.00								3:	880.000000 MHz	-16.937 dB
-5.00								4:	300.00000 MHz	-16.870 %B
							$+ \neq$	<u>n</u>	945.00000 MHz	21 641 dB
-10.00							+ /-			-
-15.00	P				<u> </u>		+/-			
-20.00					1	104	∖//			
-25.00		ļ				2/				
30.00						Ч	Y			
35.00										
-35.00 40.00	Ch 1 Avg =	20								
		1 Sec.								
Ch1; \$	itart 335.000 f	4Hz	NG			+>		1:		40 420 0
Ch1:5	Start 335.000	4Hz		<u> </u>				1: ≥2: 3: 4: 5:	Stop 800,000000 MHz 27,676 pF 835,00000 MHz 902,00 pH 900,00000 MHz 17,263 pF 900,00000 MHz 12,080 pF 945,000000 MHz 1,3906 nH	40.420 Ω -7.1883 Ω 52.216 Ω 4.7323 Ω 62.123 Ω 62.123 Ω -10.477 Ω 52.237 Ω -14.639 Ω 51.835 Ω 8.2571 Ω

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FCC ID: A3LSMG998U		HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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#### **DASY5 E-field Result**

#### Date: 19.02.2019

Test Laboratory: SPEAG Lab2

# DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003

 $\begin{array}{l} \mbox{Communication System: UID 0 - CW ; Frequency: 835 MHz } \\ \mbox{Medium parameters used: } \sigma = 0 \ S/m, \ \epsilon_r = 1; \ \rho = 0 \ kg/m^3 \\ \mbox{Phantom section: RF Section} \\ \mbox{Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)} \\ \end{array}$ 

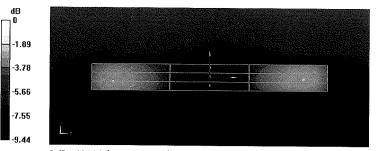
DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 835 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

#### Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm Reference Value = 127.3 V/m; Power Drift = 0.04 dB Applied MIF = 0.00 dB RF audio interference level = 40.44 dBV/m Emission category: M3

> MIF scaled E-field Grid 1 M4 Grid 2 M3 Grid 3 M3 39.75 dBV/m 40.43 dBV/m 40.43 dBV/m Grid 4 **M4** Grid 5 M4 Grid 6 M4 35.35 dBV/m 35.75 dBV/m 35.73 dBV/m Grid 7 M3 Grid 8 M3 Grid 9 **M3** 40.15 dBV/m 40.44 dBV/m 40.36 dBV/m



0 dB = 105.2 V/m = 40.44 dBV/m

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# **Calibration Laboratory of**

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland

Accredited by the Swiss Accreditation Service (SAS)



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 Swiss Callbration Service

Accreditation No.: SCS 0108

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates Client PC Test

Certificate No: CD1880V3-1137\_Feb19

Object	CD1880V3 - SN	: 1137	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proc	edure for Validation Sources in a	ir 🗸 🗸
			3/19/2
Calibration date:	February 19, 20	19	
This calibration certificate docum	ents the traceability to nat	ional standards, which realize the physical ur	its of measurements (SI).
		probability are given on the following pages ar	
All calibrations have been condu	cted in the closed laborate	ry facility: environment temperature (22 $\pm$ 3) $^{\circ}$	C and humidity < 70%.
Calibration Equipment used (M&	TE critical for calibration)		
Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
ower sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
ower sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
leference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19
ype-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02683)	Apr-19
Probe EF3DV3	SN: 4013	03-Jan-19 (No. EF3-4013_Jan19)	Jan-20
DAE4	SN: 781	09-Jan-19 (No. DAE4-781_Jan19)	Jan-20
Secondary Standards	ID #	Check Date (in house)	
ower meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-17)	Scheduled Check
ower sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Oct-17)	In house check: Oct-20
ower sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
F generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-17)	In house check: Oct-20
etwork Analyzer HP 8358A	SN: US41080477	31-Mar-14 (in house check Oct-17)	In house check: Oct-20 In house check: Oct-19
	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	Signature
			VOI -
pproved by:	Katja Pokovic	Technical Manager	والمستحد والمعادين والمعالية المستنية المستنية المستحد المستحد المستنية المستنية المستنية المستنية المستنية ال
pproved by:	Katja Pokovic	Technical Manager	fllt

Certificate No: CD1880V3-1137\_Feb19

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# Calibration Laboratory of Schmid & Partner

Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst C Service suisse d'étalonnage S Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

#### References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids,

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	······································

#### Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	95.0 V/m = 39.55 dBV/m	
Maximum measured above low end	100 mW input power	94.9 V/m = 39.55 dBV/m	
Averaged maximum above arm	100 mW input power	95.0 V/m ± 12.8 % (k=2)	

#### Maximum Field values at 1880 MHz

.

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	88.9 V/m = 38.98 dBV/m
Maximum measured above low end	100 mW input power	86.6 V/m = 38.75 dBV/m
Averaged maximum above arm	100 mW input power	87.8 V/m ± 12.8 % (k=2)

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# Appendix (Additional assessments outside the scope of SCS 0108)

### **Antenna Parameters**

**Nominal Frequencies** 

Frequency	Return Loss	<b>Impedance</b> 54.4 Ω + 6.5 jΩ	
1730 MHz	22.5 dB		
1880 MHz	21.1 dB	55.9 Ω + 7.2 jΩ	
1900 MHz	21.0 dB	59.0 Ω + 3.6 jΩ	
1950 MHz	27.3 dB	53.0 Ω - 3.3 jΩ	
2000 MHz	20.3 dB	42.4 Ω + 4.8 jΩ	

# 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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# Impedance Measurement Plot

le ⊻iew <u>C</u> hannel Sw <u>e</u> ep Calji	bration <u>T</u> race <u>S</u> cale i	Marker System <u>W</u> inc	łow <u>H</u> elp		
7.00	]	I I	1:	1.‡30000 GHz	-22,459 dE
2.00				1.880000 GHz	21.146.66
3.00			3:	4.900000 GHz	-21.002.08
8.00			-Arma	1.950000 GHz	-27.332 dt
				2	20.275.df
13.00					
18.00					
23.00		An A	l l		
		7 3 1 13			
28,00					
83.00	Y	4∨			
8.00					
43,00 Ch 1 Avg = 20					
Ch1: Start 1,38000 GHz		<pre></pre>	1.		
			1:	1.730000 GHz	54.408 Ω
		76	1:		54.408 Ω 6.5341 Ω
Christali 138000 Urz			>2:	1.730000 GHz 601.12 pH	54.408 Ω 6.5341 Ω 55.885 Ω
CIT: Stall 1.35000 GF2				1.730000 GHz 601.12 pH 1.880000 GHz 609.67 pH 1.900000 GHz	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω
CIT: Stall 1.35000 UR2	Á		>2:	1.730000 GHz 601.12 pH 1.880000 GHz 609.67 pH 1.900000 GHz 303.81 pH	2.38000 GHz 54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω
CIT: Statt 1.35000 UT2	Å		>2:	1.730000 GHz 601.12 pH 1.880000 GHz 609.67 pH 1.900600 GHz 303.81 pH 1.950000 GHz	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω
CHI, Statt 1,33000 UH2			>2: 3: 4:	1.730000 GHz 601.12 pH 1.880000 GHz 603.67 pH 1.300600 GHz 303.81 pH 1.950000 GHz 24.752 pF	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω
CHI Statt 133000 UR2	Á		>2:	1.730000 GHz 601.12 pH 1.80000 GHz 609.67 pH 1.900000 GHz 303.81 pH 1.950000 GHz 24.752 pF 2.00000 GHz	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω 42.436 Ω
	<u> </u>		>2: 3: 4:	1.730000 GHz 601.12 pH 1.880000 GHz 603.67 pH 1.300600 GHz 303.81 pH 1.950000 GHz 24.752 pF	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω
			>2: 3: 4:	1.730000 GHz 601.12 pH 1.80000 GHz 609.67 pH 1.900000 GHz 303.81 pH 1.950000 GHz 24.752 pF 2.00000 GHz	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω 42.436 Ω
	<u> </u>		>2: 3: 4:	1.730000 GHz 601.12 pH 1.80000 GHz 609.67 pH 1.900000 GHz 303.81 pH 1.950000 GHz 24.752 pF 2.00000 GHz	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω 42.436 Ω
			>2: 3: 4:	1.730000 GHz 601.12 pH 1.80000 GHz 609.67 pH 1.900000 GHz 303.81 pH 1.950000 GHz 24.752 pF 2.00000 GHz	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω 42.436 Ω
Ch 1 Avg = 20			>2: 3: 4:	1.730000 GHz 601.12 pH 1.880000 GHz 609.67 pH 1.90000 GHz 303.81 pH 1.950000 GHz 24.752 pF 2.000000 GHz 383.29 pH	54.408 Ω 6.534 Ω 55.885 Ω 7.2016 Ω 53.025 Ω 52.957 Ω -3.2375 Ω -42.436 Ω 4.8166 Ω
			>2: 3: 4:	1.730000 GHz 601.12 pH 1.880000 GHz 609.67 pH 1.90000 GHz 303.81 pH 1.950000 GHz 24.752 pF 2.000000 GHz 383.29 pH	54.408 Ω 6.5341 Ω 55.885 Ω 7.2016 Ω 59.017 Ω 3.6269 Ω 52.957 Ω -3.2975 Ω 42.436 Ω

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#### **DASY5 E-field Result**

#### Date: 19.02.2019

Test Laboratory: SPEAG Lab2

# DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: UID 0 - CW ; Frequency: 1880 MHz, Frequency: 1730 MHz Medium parameters used:  $\sigma = 0$  S/m,  $\varepsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup> Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 1880 MHz, ConvF(1, 1, 1) @ 1730 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 151.5 V/m; Power Drift = 0.02 dB Applied MIF = 0.00 dB RF audio interference level = 38.98 dBV/m Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 <b>M2</b>	Grid 3 M2
38.55 dBV/m	38.98 dBV/m	38.93 dBV/m
Grid 4 M2	Grid 5 <b>M2</b>	Grid 6 <b>M2</b>
35.71 dBV/m	35.97 dBV/m	35.96 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
38.31 dBV/m	38.75 dBV/m	38.73 dBV/m

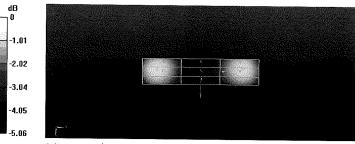
Certificate No: CD1880V3-1137\_Feb19

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FCC ID: A3LSMG998U	PCTEST: Prout is lie port of @ research	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Dipole E-Field measurement @ 1880MHz /E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 165.0 V/m; Power Drift = 0.03 dB Applied MIF = 0.00 dB RF audio interference level = 39.55 dBV/m Emission category: M2

	Grid 2 M2 39.55 dBV/m	Grid 3 M2 39.51 dBV/m
	Grid 5 M2	
36.57 dBV/m	36.95 dBV/m	36.95 dBV/m
Grid 7 M2	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
39.05 dBV/m	39.55 dBV/m	39.53 dBV/m



0 dB = 88.87 V/m = 38.98 dBV/m

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 Swiss Calibration Service

Accreditation No.: SCS 0108

Certificate No: CD2600V3-1012\_Feb19

CALIBRATION	CERTIFICAT	E	
Object	CD2600V3 - SN	: 1012	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proc	edure for Validation Sources in a	ir /0.4 3/19/24
			3/19/22
Calibration date:	February 19, 20 <sup>-</sup>	19	
The measurements and the unce	ortainties with confidence p	ional standards, which realize the physical un probability are given on the following pages ar ny facility: environment temperature (22 $\pm$ 3)°(	nd are part of the certificate.
Primary Standards	D #	Cal Date (Certificate No.)	
Power meter NBP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Scheduled Calibration
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672/02673) 04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02082)	Apr-19
Probe EF3DV3	SN: 4013	03-Jan-19 (No. EF3-4013_Jan19)	Apr-19 Jan-20
DAE4	SN: 781	09-Jan-19 (No. DAE4-781_Jan19)	Jan-20
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Oct-17)	In house check: Oct-20
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-17)	In house check: Oct-20
Network Analyzer HP 8358A	SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check: Oct-19
De l'Ilevente et tra	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	VA
Approved by:	Katja Pokovic	Technical Manager	Elle
		full without written approval of the laboratory.	Issued: February 20, 2019

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<sup>6/22/2020</sup> 

#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 0108

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#### References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

# Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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# **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	······································
Frequency	2600 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values at 2600 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	85.6 V/m = 38.65 dBV/m	
Maximum measured above low end	100 mW input power	84.7 V/m = 38.56 dBV/m	
Averaged maximum above arm	100 mW input power	85.2 V/m ± 12.8 % (k=2)	

# Appendix (Additional assessments outside the scope of SCS 0108)

#### **Antenna Parameters**

Frequency	Return Loss	Impedance
2450 MHz	20.5 dB	42.7 Ω - 4.8 jΩ
2550 MHz	32.1 dB	48.9 Ω + 2.2 jΩ
2600 MHz	39.6 dB	50.3 Ω + 1.0 jΩ
2650 MHz	30.4 dB	53.0 Ω + 0.9 jΩ
2750 MHz	20.9 dB	48.9 Ω - 8.9 jΩ

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

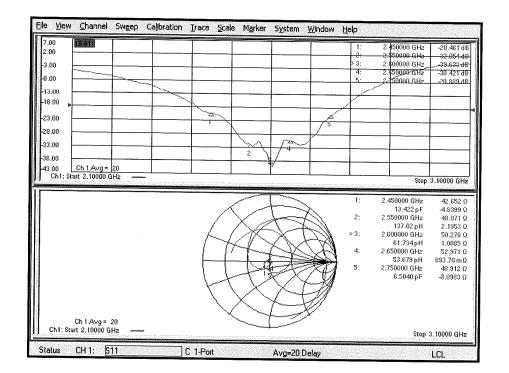
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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# Impedance Measurement Plot



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### **DASY5 E-field Result**

#### Date: 19.02.2019

Test Laboratory: SPEAG Lab2

# DUT: HAC Dipole 2600 MHz; Type: CD2600V3; Serial: CD2600V3 - SN: 1012

 $\begin{array}{l} \mbox{Communication System: UID 0 - CW ; Frequency: 2600 MHz} \\ \mbox{Medium parameters used: } \sigma = 0 \mbox{ S/m, } \epsilon_r = 1; \mbox{$\rho$} = 0 \mbox{ kg/m}^3 \\ \mbox{Phantom section: RF Section} \\ \mbox{Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)} \\ \end{array}$ 

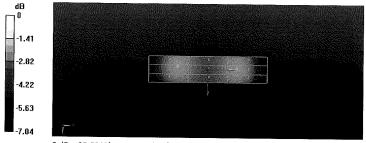
DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 2600 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
   Phantom: HAC Tast Arch with AMCCO Time: SD II
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

Dipole E-Field measurement @ 2600MHz - with/E-Scan - 2600MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 62.82 V/m; Power Drift = -0.01 dB Applied MIF = 0.00 dB RF audio interference level = 38.65 dBV/m Emission category: M2

MIF scaled E-field

Grid 1 <b>M2</b>	Grid 2 <b>M2</b>	Grid 3 <b>M2</b>
38.09 dBV/m	38.56 dBV/m	38.54 dBV/m
Grid 4 M2	Grid 5 <b>M2</b>	Grid 6 M2
37.82 dBV/m	38.06 dBV/m	38.02 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
38.36 dBV/m	38.65 dBV/m	38.56 dBV/m



0 dB = 85.60 V/m = 38.65 dBV/m

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Client PC Test

Certificate No: CD3500V3-1005\_Oct20

Object	CD3500V3 - SN:	1005	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proce	edure for Validation Sources in ai	r
Calibration date:	October 20, 2020	)	
The measurements and the uncert All calibrations have been conducted	ainties with confidence p ed in the closed laborator	onal standards, which realize the physical un robability are given on the following pages an ry facility: environment temperature (22 ± 3)°(	ad are part of the certificate.
Calibration Equipment used (M&TE Primary Standards	Critical for calibration)	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	01-Apr-20 (No. 217-03100/03101)	Apr-21
Power sensor NRP-Z91	SN: 103244	01-Apr-20 (No. 217-03100)	Apr-21
Power sensor NRP-Z91	SN: 103245	01-Apr-20 (No. 217-03101)	Apr-21
Reference 20 dB Attenuator	SN: BH9394 (20k)	31-Mar-20 (No. 217-03106)	Apr-21
Type-N mismatch combination	SN: 310982 / 06327	31-Mar-20 (No. 217-03104)	Apr-21
Probe EF3DV3	SN: 4013	31-Dec-19 (No. EF3-4013_Dec19)	Dec-20
DAE4	SN: 781	27-Dec-19 (No. DAE4-781_Dec19)	Dec-20
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-20)	In house check: Oct-23
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Oct-20)	In house check: Oct-23
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-20)	In house check: Oct-23
RF generator R&S SMT-06	SN: 837633/005	10-Jan-19 (in house check Oct-20)	In house check: Oct-23
Network Analyzer Agilent E8358A	SN: US41080477	31-Mar-14 (in house check Oct-20)	In house check: Oct-21
	Name	Function	Signature
Calibrated by:	Lelf Klysner	Laboratory Technician	Sel Illen
	Katja Pokovic	Technical Manager	lette
Approved by:			/ / /

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Accreditation No.: SCS 0108

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#### References

- [1] ANSI-C63.19-2011
  - American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic E-field probe with 100 mW forward
  power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the
  dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms.
  Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one
  line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any nonparallelity to the measurement plane as well as the sensor displacement. The E-field value stated as
  calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY5	V52.10.4
HAC Test Arch	
15 mm	
dx, dy = 5 mm	
3500 MHz ± 1 MHz 3900 MHz ± 1 MHz	
< 0.05 dB	
	HAC Test Arch 15 mm dx, dy = 5 mm 3500 MHz ± 1 MHz 3900 MHz ± 1 MHz

#### Maximum Field values at 3500 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	85.3 V/m = 38.61 dBV/m
Maximum measured above low end	100 mW input power	83.6 V/m = 38.44 dBV/m
Averaged maximum above arm	100 mW input power	84.4 V/m ± 12.8 % (k=2)

# Maximum Field values at 3900 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	82.0 V/m = 38.28 dBV/m	
Maximum measured above low end	100 mW input power	79.9 V/m = 38.05 dBV/m	
Averaged maximum above arm	100 mW input power	81.0 V/m ± 12.8 % (k=2)	

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### Appendix (Additional assessments outside the scope of SCS 0108)

#### **Antenna Parameters**

#### **Nominal Frequencies**

Frequency	Return Loss	Impedance
3300 MHz	22.3 dB	58.2 Ω + 0.9 jΩ
3400 MHz	31.4 dB	52.7 Ω - 0.2 jΩ
3500 MHz	25.0 dB	55.4 Ω - 2.4 jΩ
3600 MHz	21.1 dB	49.4 Ω - 8.8 jΩ
3700 MHz	19.6 dB	41.0 Ω - 3.2 jΩ

#### **Additional Frequencies**

Frequency	Return Loss Imped	
3900 MHz	17.0 dB	47.7 Ω + 13.8 jΩ

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

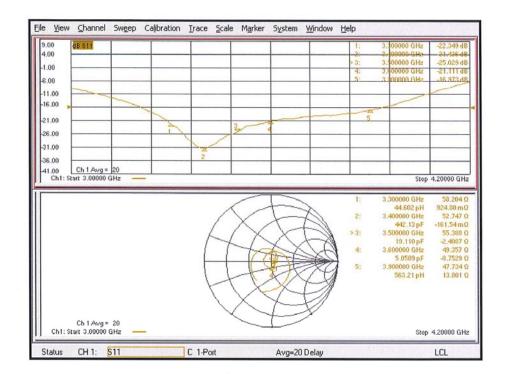
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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### **Impedance Measurement Plot**



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### DASY5 E-field Result

Date: 20.10.2020

Test Laboratory: SPEAG Lab2

# DUT: HAC Dipole 3500 MHz; Type: CD3500V3; Serial: CD3500V3 - SN: 1005

Communication System: UID 0 - CW ; Frequency: 3500 MHz, Frequency: 3900 MHz Medium parameters used:  $\sigma = 0$  S/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup> Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 3500 MHz, ConvF(1, 1, 1) @ 3900 MHz; Calibrated: 31.12.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 27.12.2019
   Phantom: HAC Test Arch with AMCC: Type: SD HAC P01 BA: Serial: 1
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.4(1527); SEMCAD X 14.6.14(7483)

Dipole E-Field measurement @ 3500MHz/E-Scan - 3500MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 34.56 V/m; Power Drift = 0.03 dB Applied MIF = 0.00 dB RF audio interference level = 38.61 dBV/m Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 <b>M2</b>	Grid 3 M2
38.24 dBV/m	38.44 dBV/m	38.36 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 <b>M2</b>
38.41 dBV/m	38.61 dBV/m	38.5 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.41 dBV/m	38.6 dBV/m	38.49 dBV/m

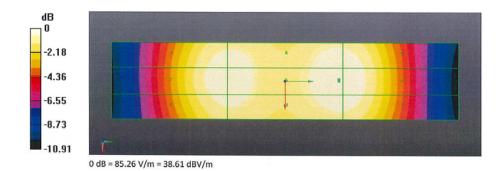
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Dipole E-Field measurement @ 3500MHz/E-Scan - 3900MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 31.52 V/m; Power Drift = -0.01 dB Applied MIF = 0.00 dB RF audio interference level = 38.28 dBV/m Emission category: M2

Grid 2 M2 38.05 dBV/m	Grid 3 M2 37.98 dBV/m
Grid 5 M2 38.28 dBV/m	Grid 6 M2 38.16 dBV/m
Grid 8 M2 38.25 dBV/m	Grid 9 M2 38.13 dBV/m



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# 16. CONCLUSION

The measurements, taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017, indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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